



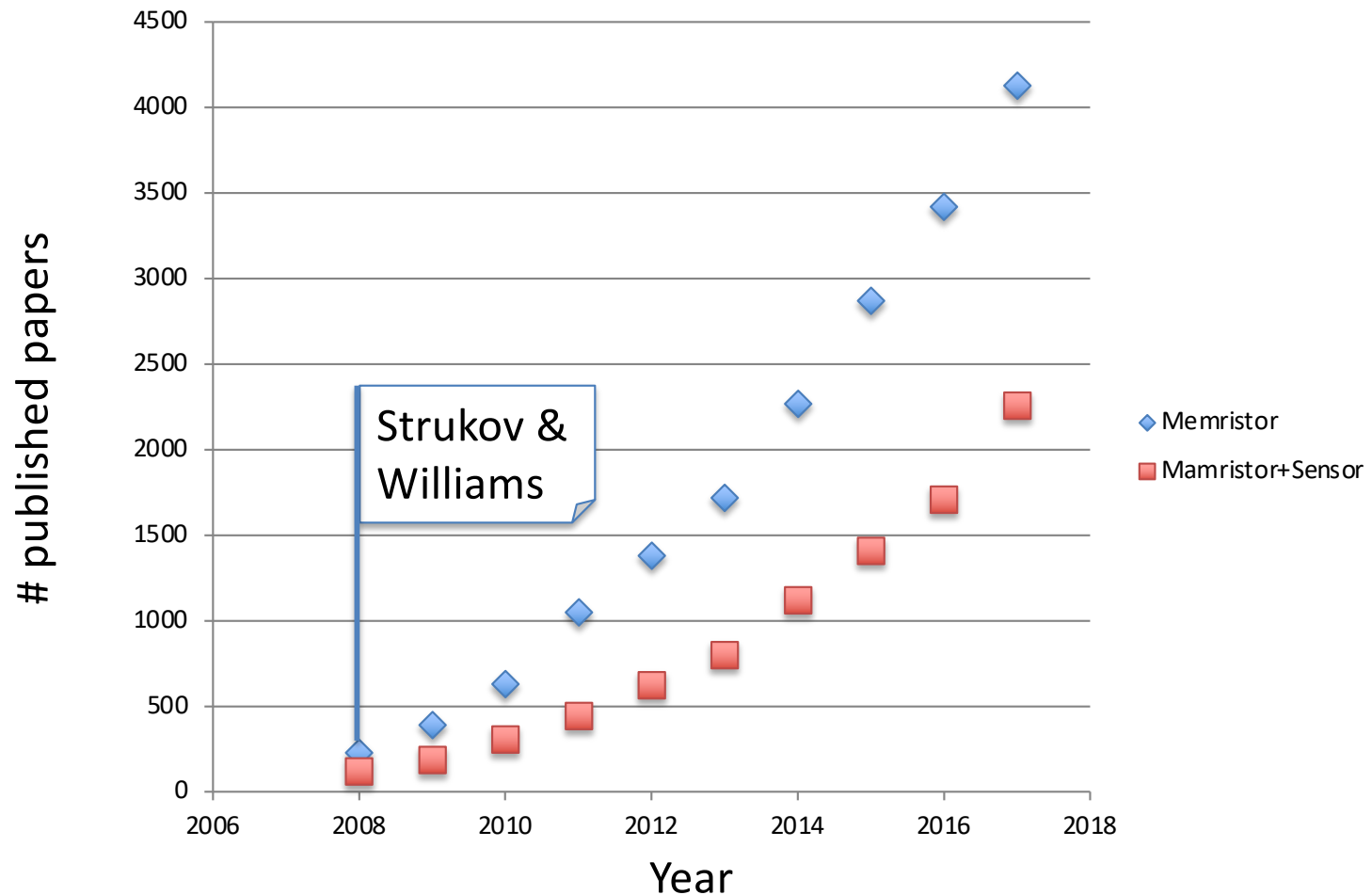
EDMI Microsystems and Microelectronics

MICRO-614: Electrochemical Nano-Bio-Sensing
and Bio/CMOS interfaces

Lecture #10

Nanotechnology to enhance
ISFET sensing: *Ultrasensitive
Memristive Biosensors*

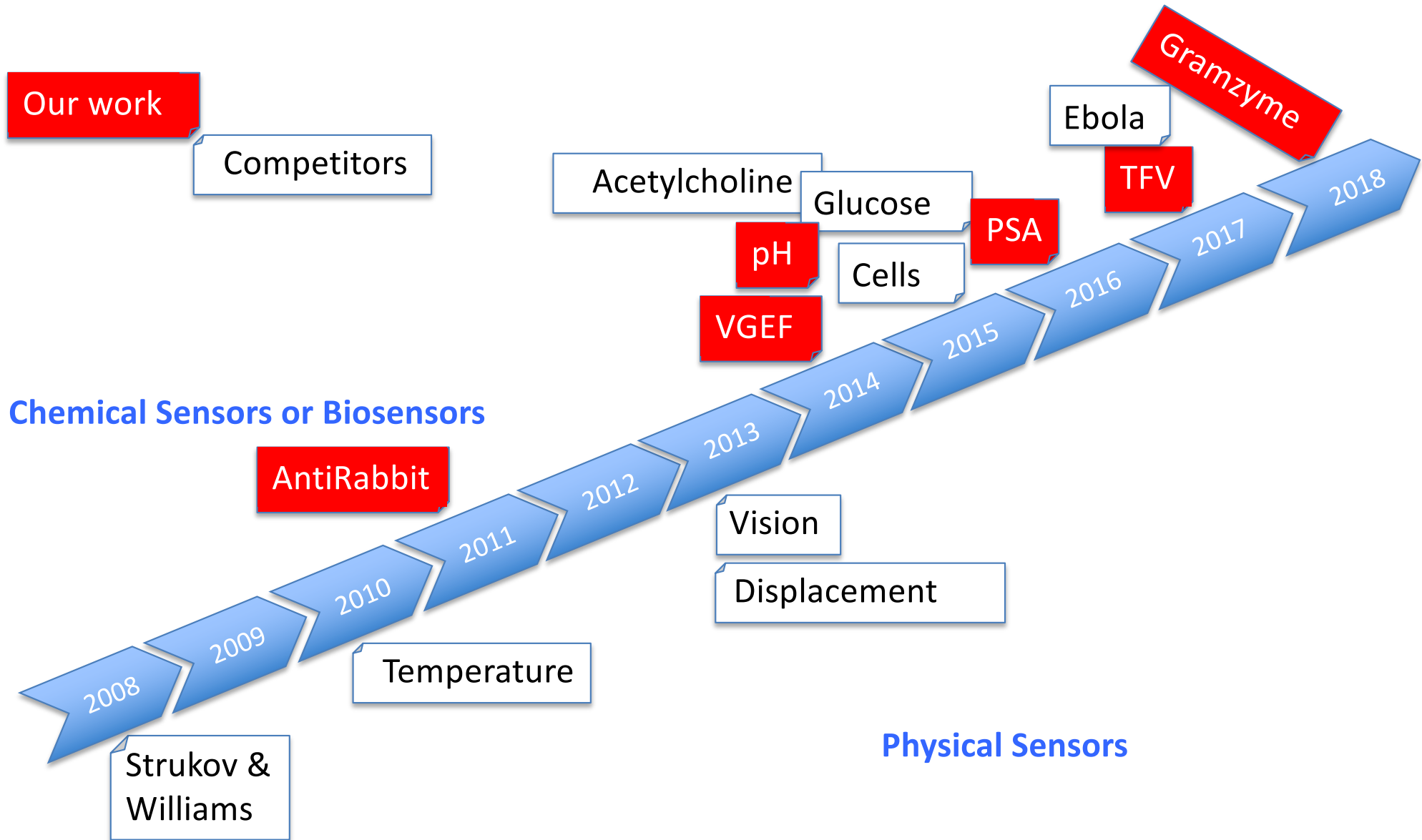
Published Works on Memristors



16.700 papers published so far from 2008 with keyword «Memristor»

10.100 papers published so far from 2008 with also keyword «Sensor»

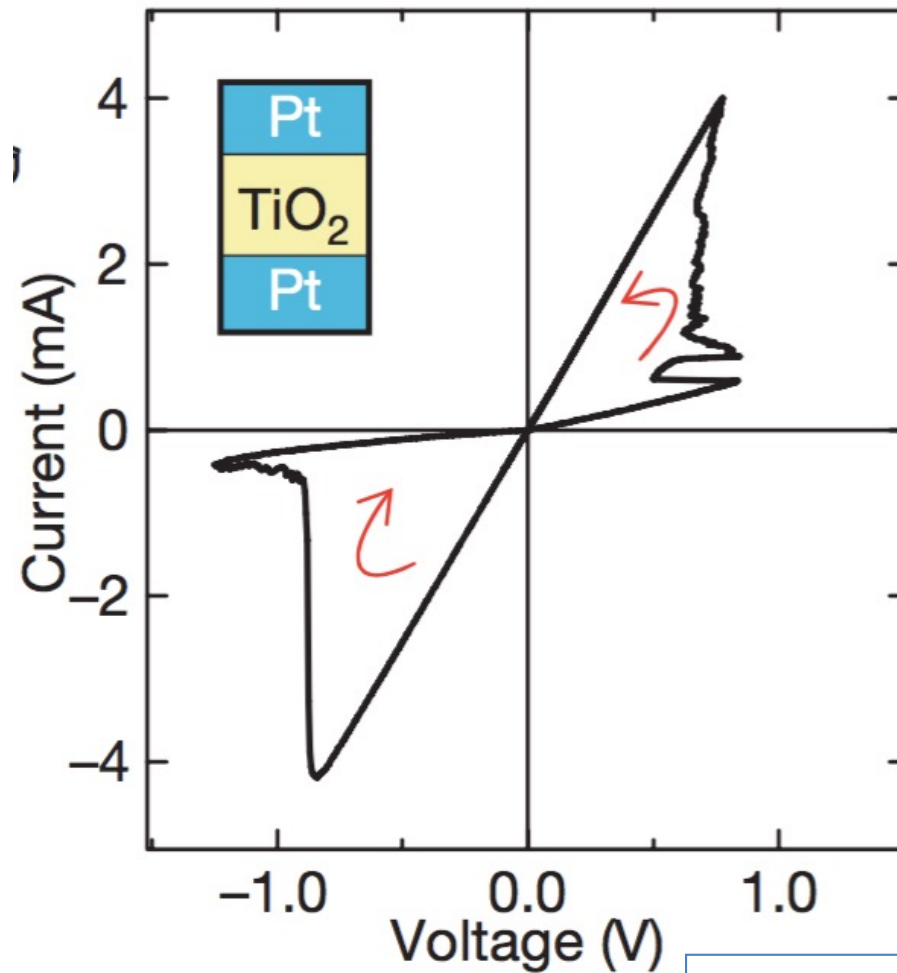
Memristive Sensors Milestones



Memristive Sensors Milestones

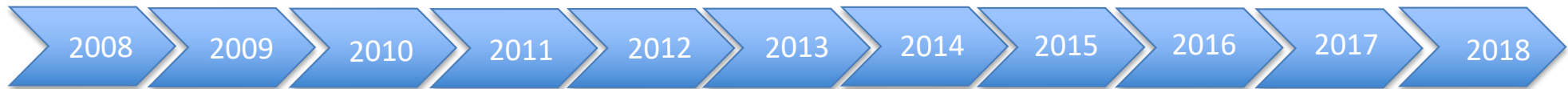


Strukov &
Williams

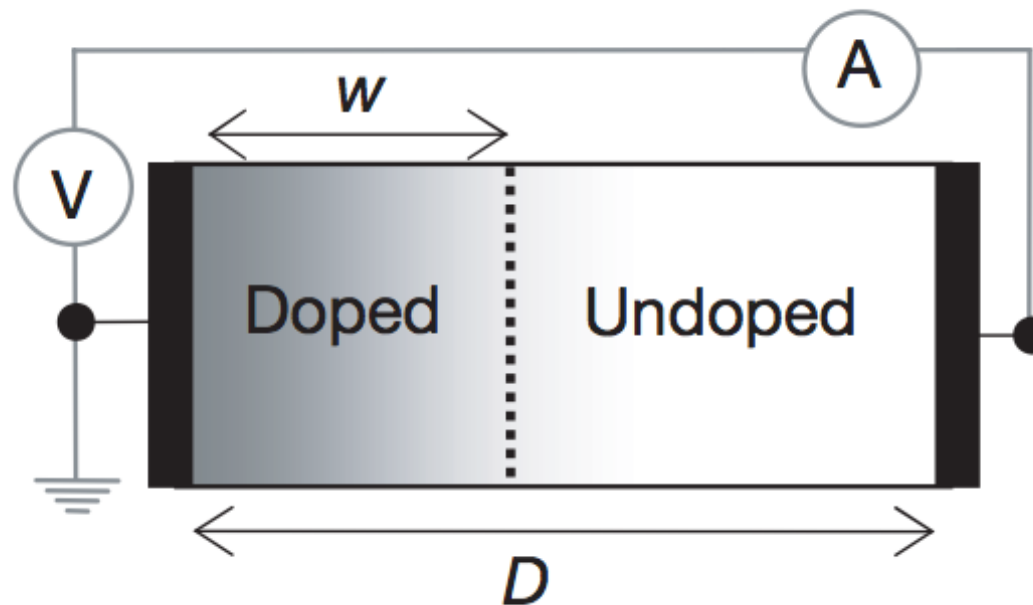


D.B. Strukov, et al S. Williams, Nature 2008

Memristive Sensors Milestones



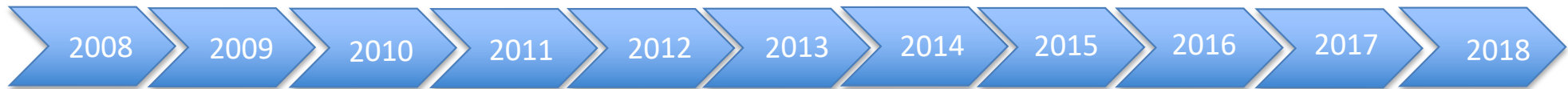
Strukov &
Williams



w-state model

D.B. Strukov, et al S. Williams, Nature 2008

Memristive Sensors Milestones



Strukov &
Williams

$$v(t) = \left(\mathcal{R}_{\text{ON}} \frac{w(t)}{D} + \mathcal{R}_{\text{OFF}} \left(1 - \frac{w(t)}{D} \right) \right) i(t) \quad (5)$$

$$\frac{dw(t)}{dt} = \mu_V \frac{\mathcal{R}_{\text{ON}}}{D} i(t) \quad (6)$$

which yields the following formula for $w(t)$:

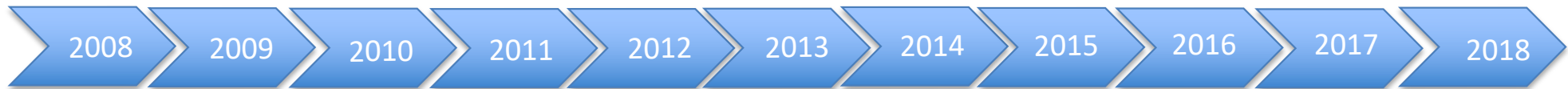
$$w(t) = \mu_V \frac{\mathcal{R}_{\text{ON}}}{D} q(t) \quad (7)$$

By inserting equation (7) into equation (5) we obtain the memristance of this system, which for $\mathcal{R}_{\text{ON}} \ll \mathcal{R}_{\text{OFF}}$ simplifies to:

$$M(q) = \mathcal{R}_{\text{OFF}} \left(1 - \frac{\mu_V \mathcal{R}_{\text{ON}}}{D^2} q(t) \right)$$

D.B. Strukov, et al S. Williams, Nature 2008

Memristive Sensors Milestones

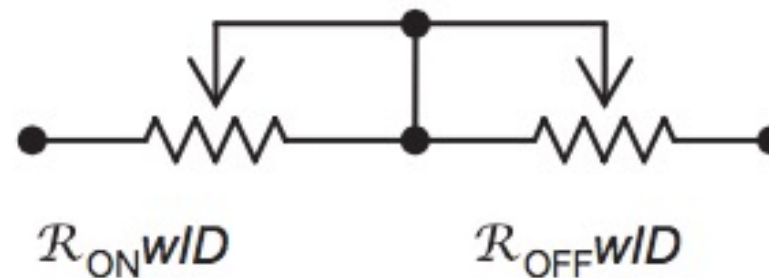


Strukov & Williams

Undoped:



Doped:

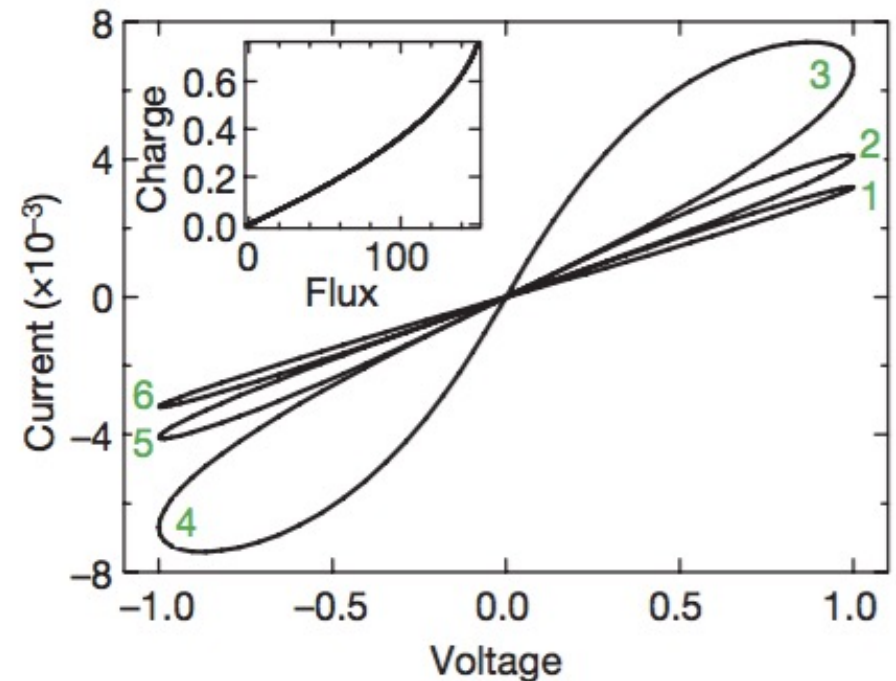
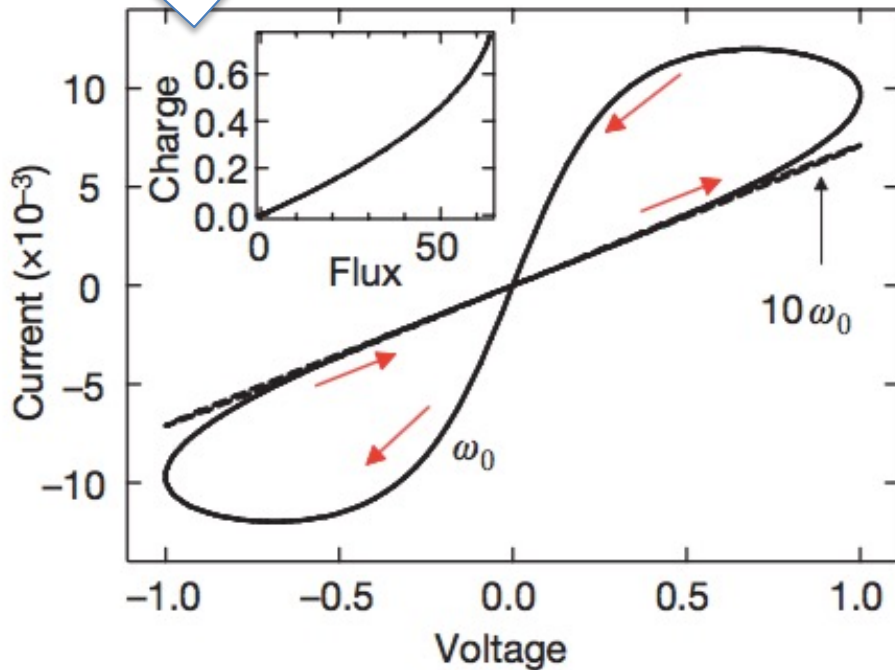


D.B. Strukov, et al S. Williams, Nature 2008

Memristive Sensors Milestones



Strukov & Williams



D.B. Strukov, et al S. Williams, Nature 2008

Limits of Detection with Antibody based Cancer Biosensors

TECHNOLOGY	Det. Limit	in Chip	Marker	Reference
QCM	0,61 nM	Yes	PSA	Y.Ukudag / Biosens. and Bioel. (submitted)
Micro-Cantiliver	10,0 pM	Yes	gene 1-8U	J.Zhang / Nature Nanotech. 1(2006) 214-220
AFM	Single Cells	No	-	Cross / Nature Nanotech 2(2007) 280-283
SPR	7,69 nM	Yes	AFP	Y. Teramura / Anal. Biochem. 365 (2007) 201–207
IS-FET	27,3 fM	Yes	PSA	G.Zheng / NATURE Biotech 10 (2005) 1294-1301
C-Measurements	62,7 nM	Yes	IgM-SCCA	S.Carrara / Sens. Actuators B136(2009) 163-172

The Limit Of Detection (LOD) is in the range 27 fM ÷ 63 nM

Limits of Detection with Aptamer based Cancer Biosensors

Table 1. State of the Art List of Reported PSA Electrochemical Aptasensors to Date

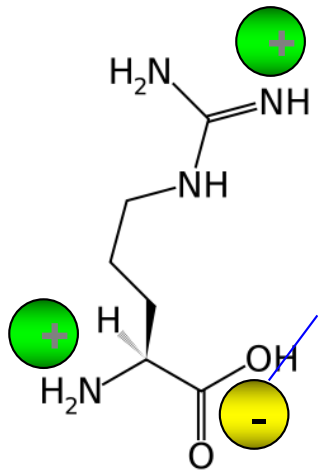
method	electrode surface	LOD	reference
quartz crystal microbalance with dissipation mode/electrochemical impedance spectroscopy (EIS)	gold electrodes	37 nM	Formisano et al. ¹⁴ (2015)
square wave voltammetry	GCE	pM range	Souada et al. ¹⁵ (2015)
EIS	gold electrodes	30 pM	Jolly et al. ¹⁶ (2015)
differential pulse voltammetry (DPV)	glassy carbon electrode (GCE)	7.6 pM	Liu et al. ¹⁷ (2012)
EIS	GCE	0.15 pM	Kavosi et al. ¹⁸ (2015)
EIS	gold electrodes	fM range	Yang et al. ¹⁹ (2015)
EIS (capacitance measurement)	gold electrodes	30 fM	Jolly et al. ²⁰ (2016)
DPV	GCE	300 aM	Kavosi et al. ¹⁸ (2015)

I. Tzouvadaki et al., Nano Letters, 16(2016) 4472-4476

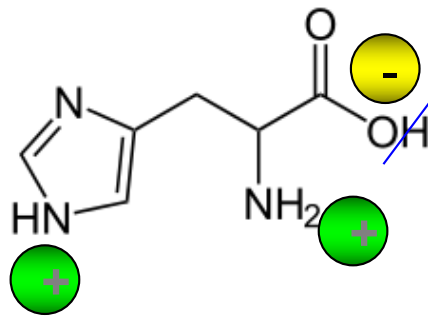
The Limit Of Detection (LOD) is in the range 300 aM ÷ 37nM

Protein Charges

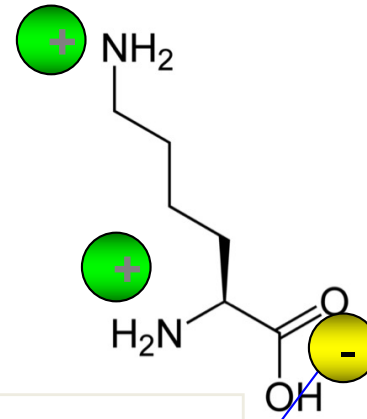
Positively Charged



Arginine

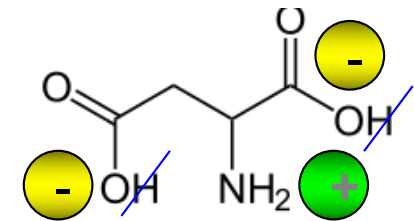


Histidine

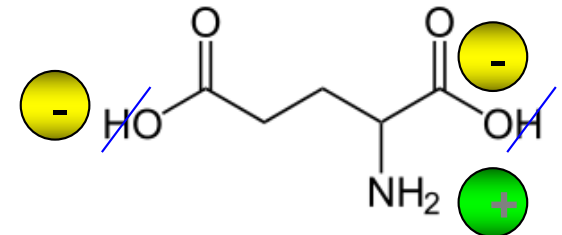


Lysine

Neg. Charged



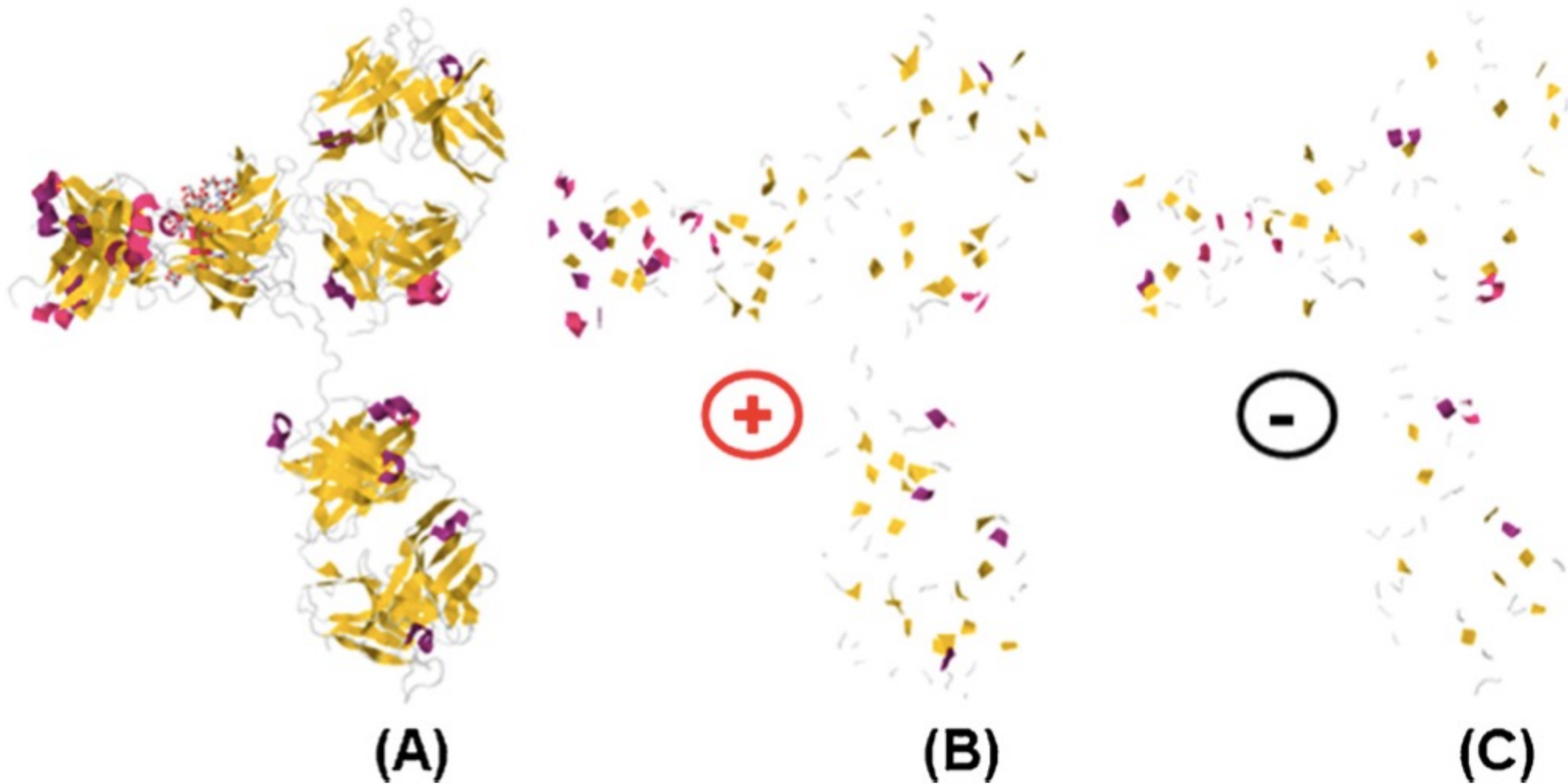
Aspartic Acid



Glutamic Acid

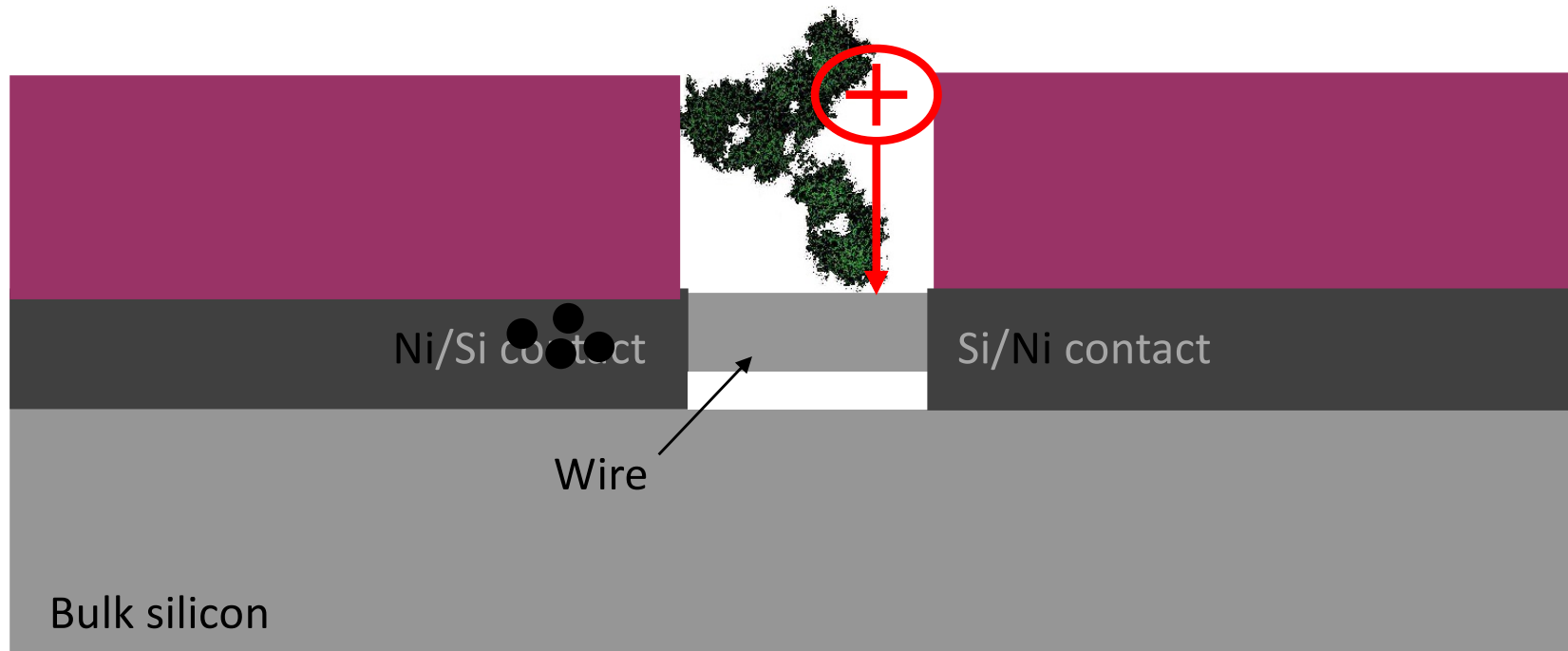
Charged Amino Acids

Protein Charges



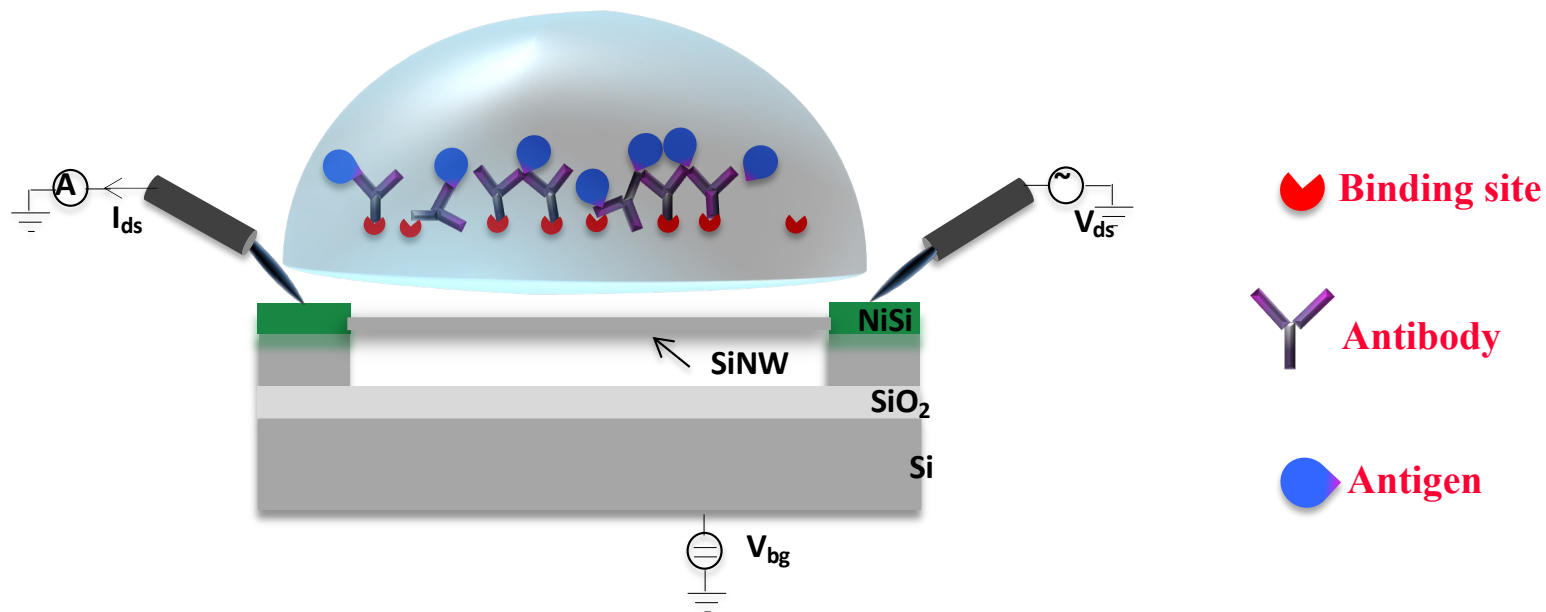
Charged Residues in an Antibody by protein DB

Charge-based-Sensing



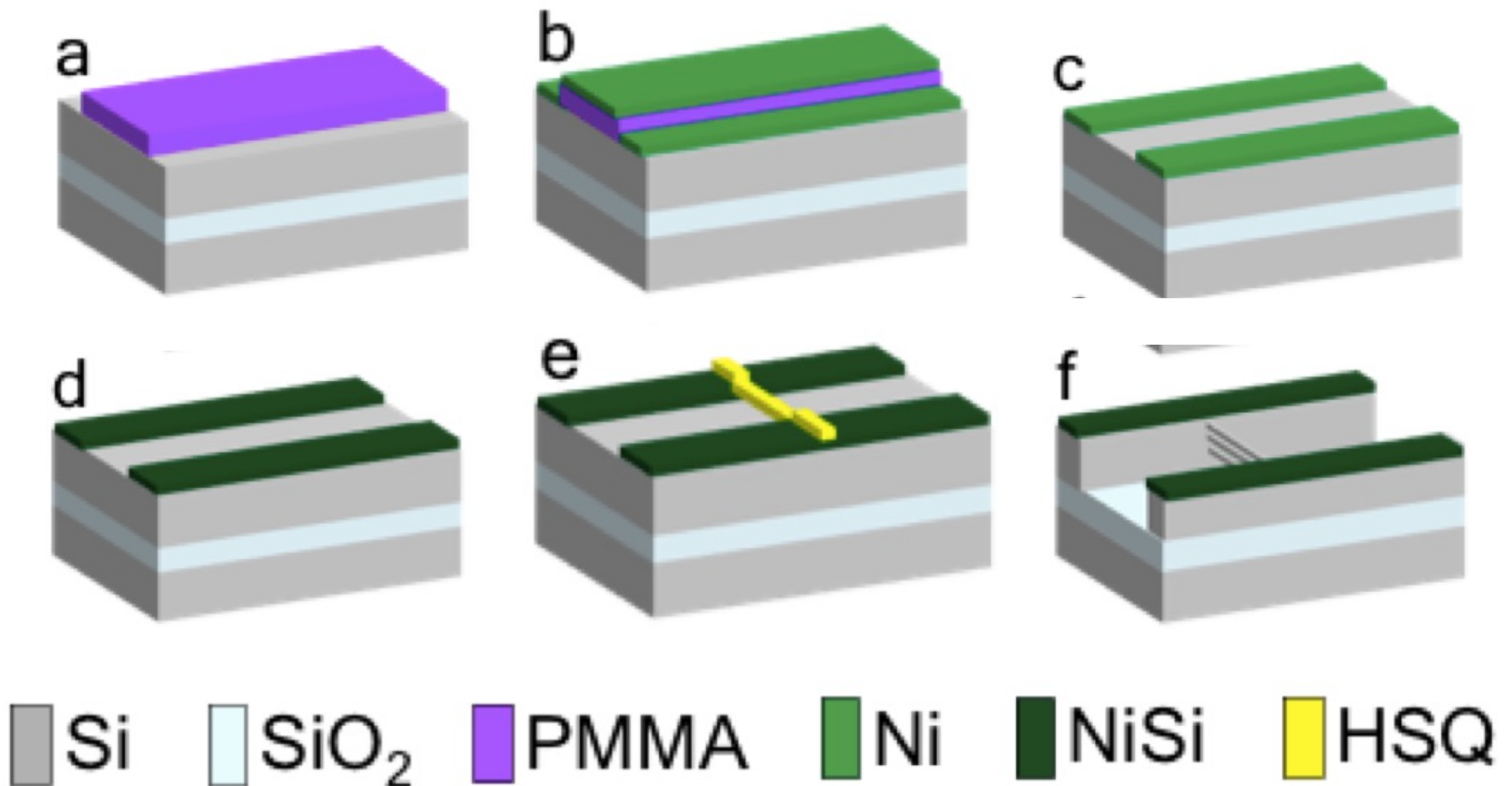
The charging from molecules affects the conductivity in the silicon channel

Bio-Functionalization



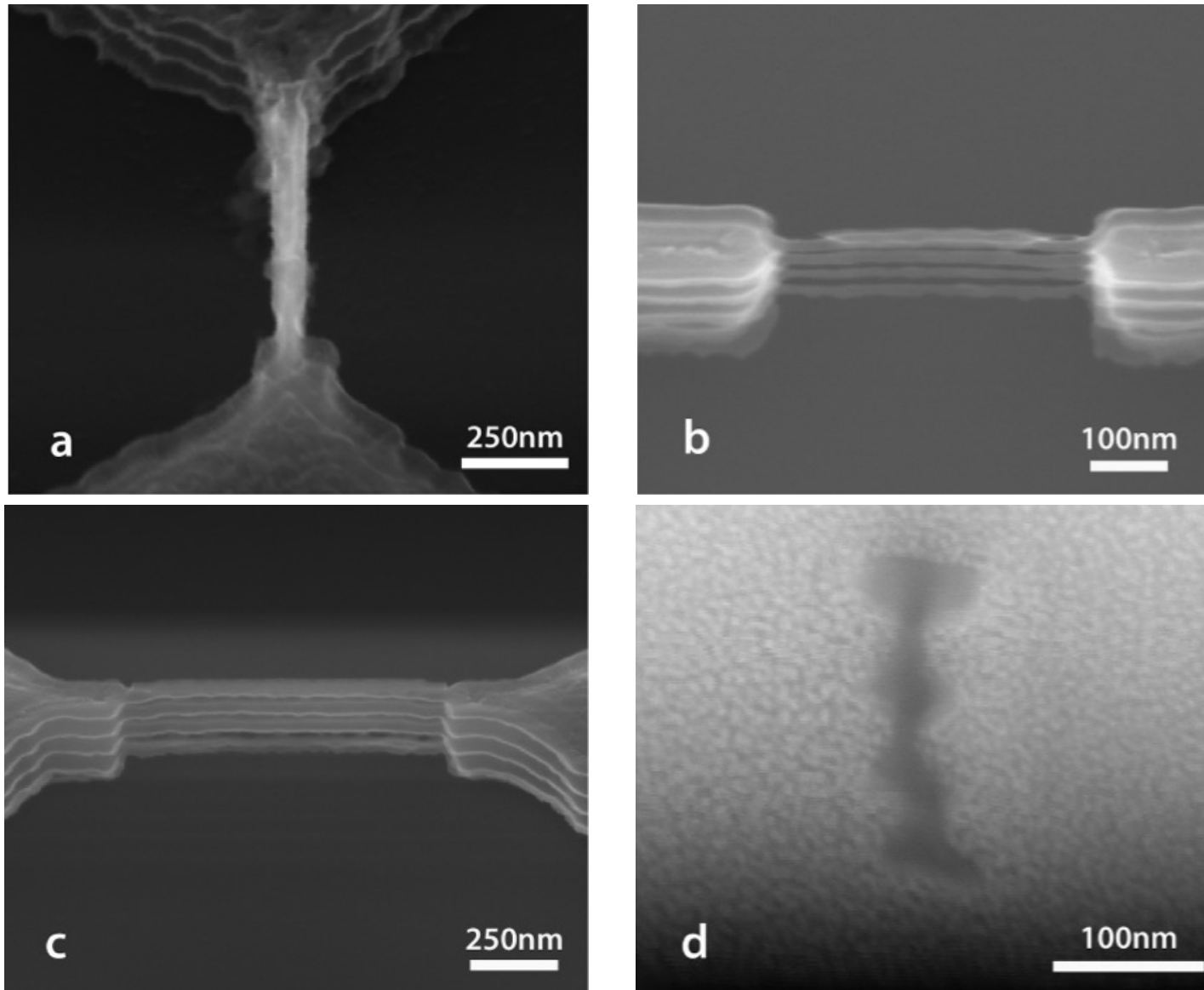
Biosensing Measures are acquired on air after the Antibodies immobilization and the Antigens uptake

Fabrication Process for Memristive Biosensors



Fabrication Results

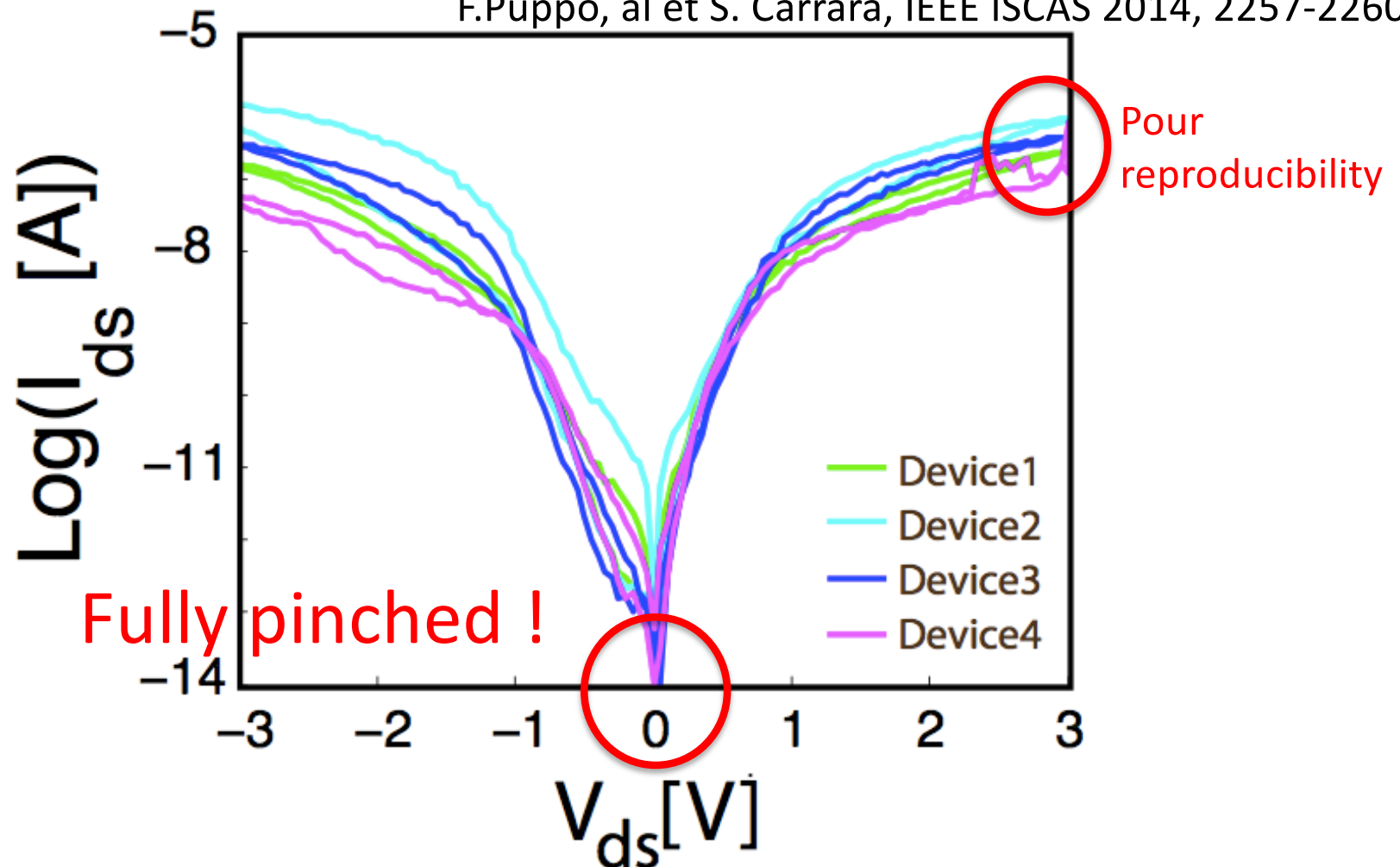
F.Puppo, al et S. Carrara, IEEE ISCAS 2014, 2257-2260



(c) S.Carrara

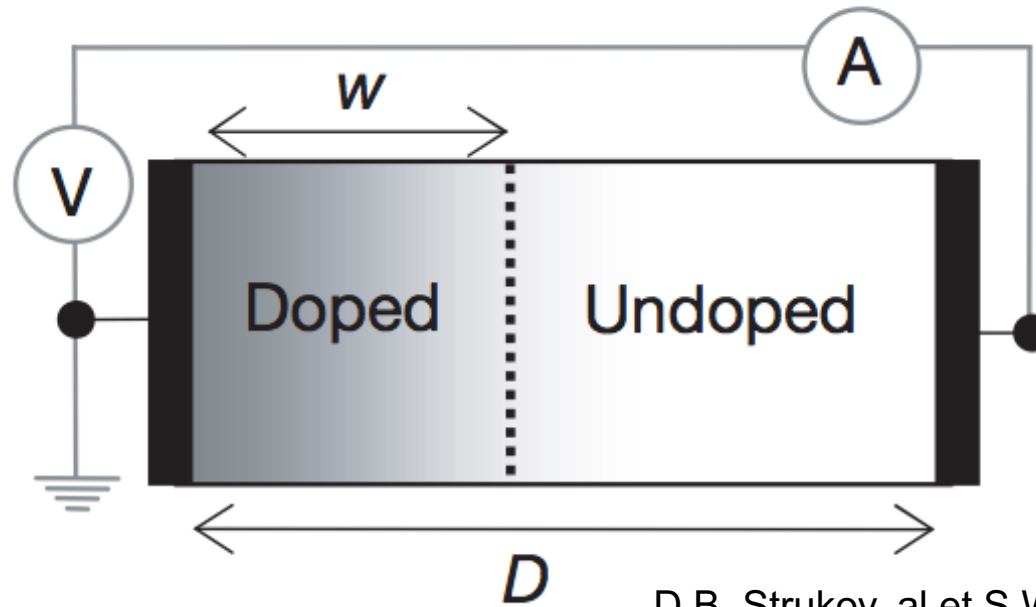
Memristive hysteresis

F.Puppo, al et S. Carrara, IEEE ISCAS 2014, 2257-2260



Fully punched Memristive Hysteresis is registered on bare nanowires

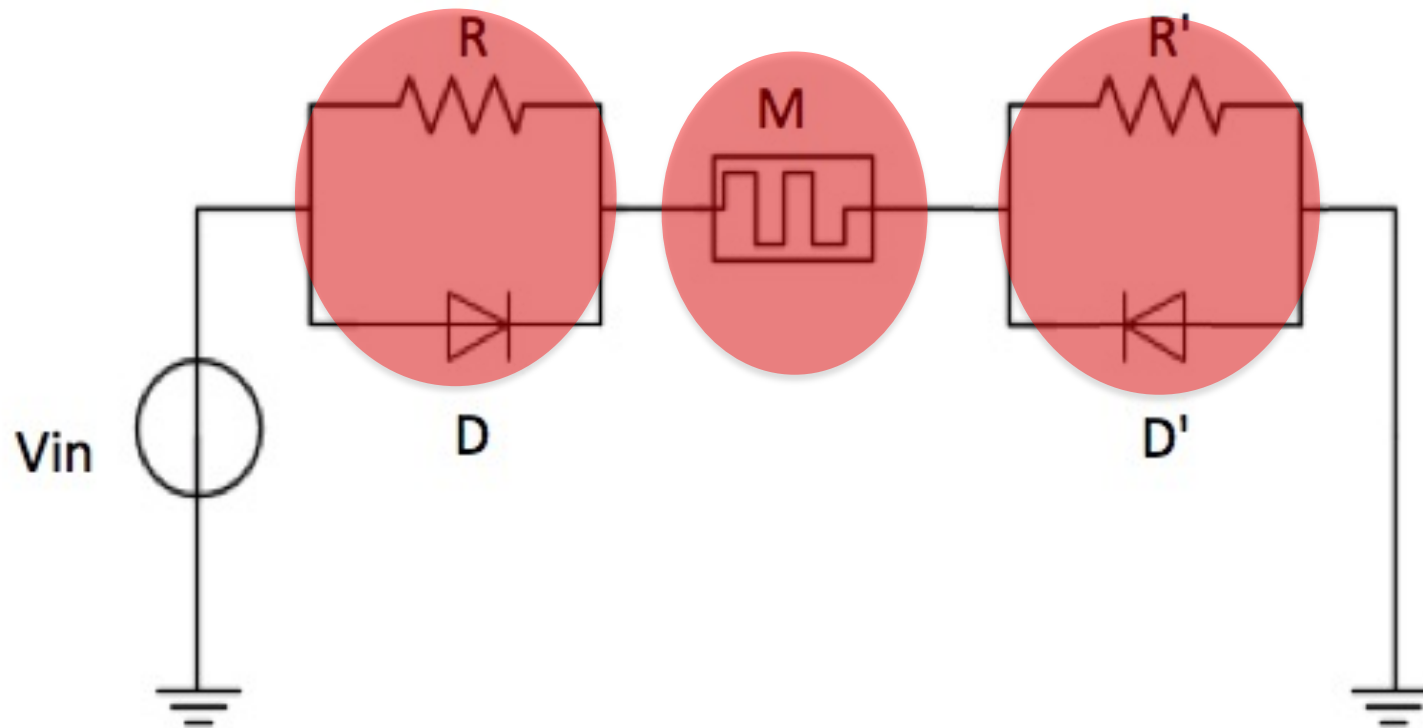
Strukov/Williams Theory



D.B. Strukov, et al et S.Williams, Nature 2008

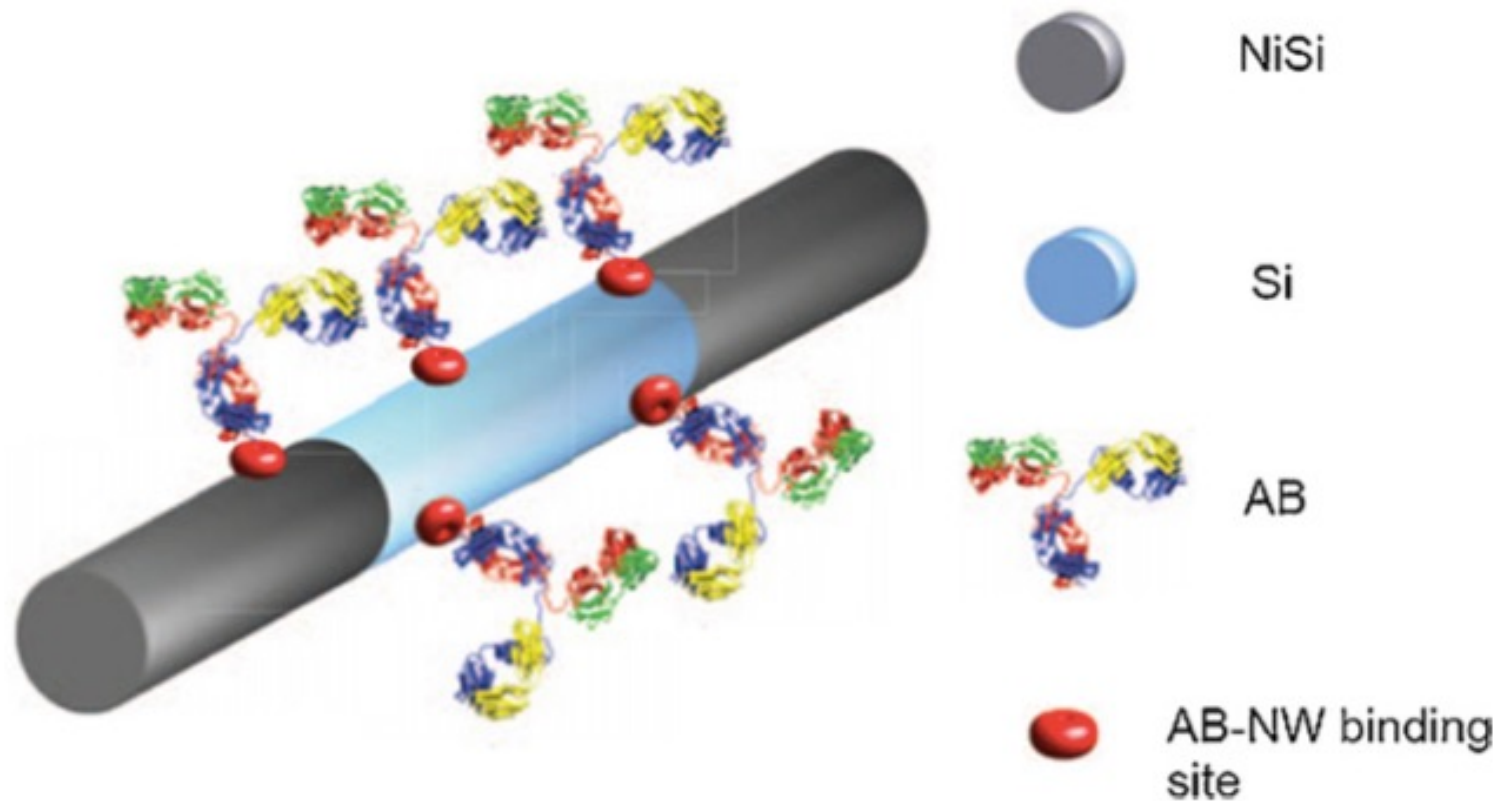
w-state model

Memristive Model



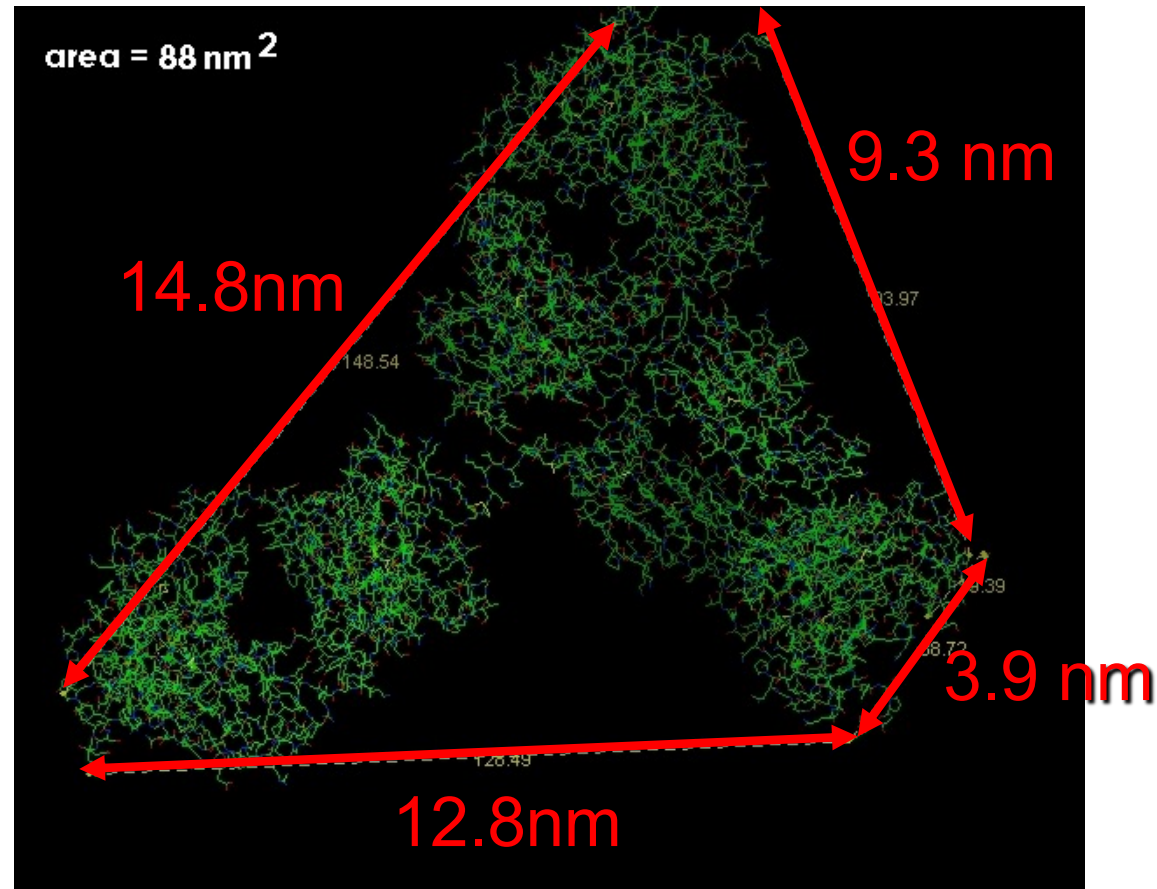
Model of our Nanowires based on a pure Memristor and two Schottky Barriers

Bio-Functionalization



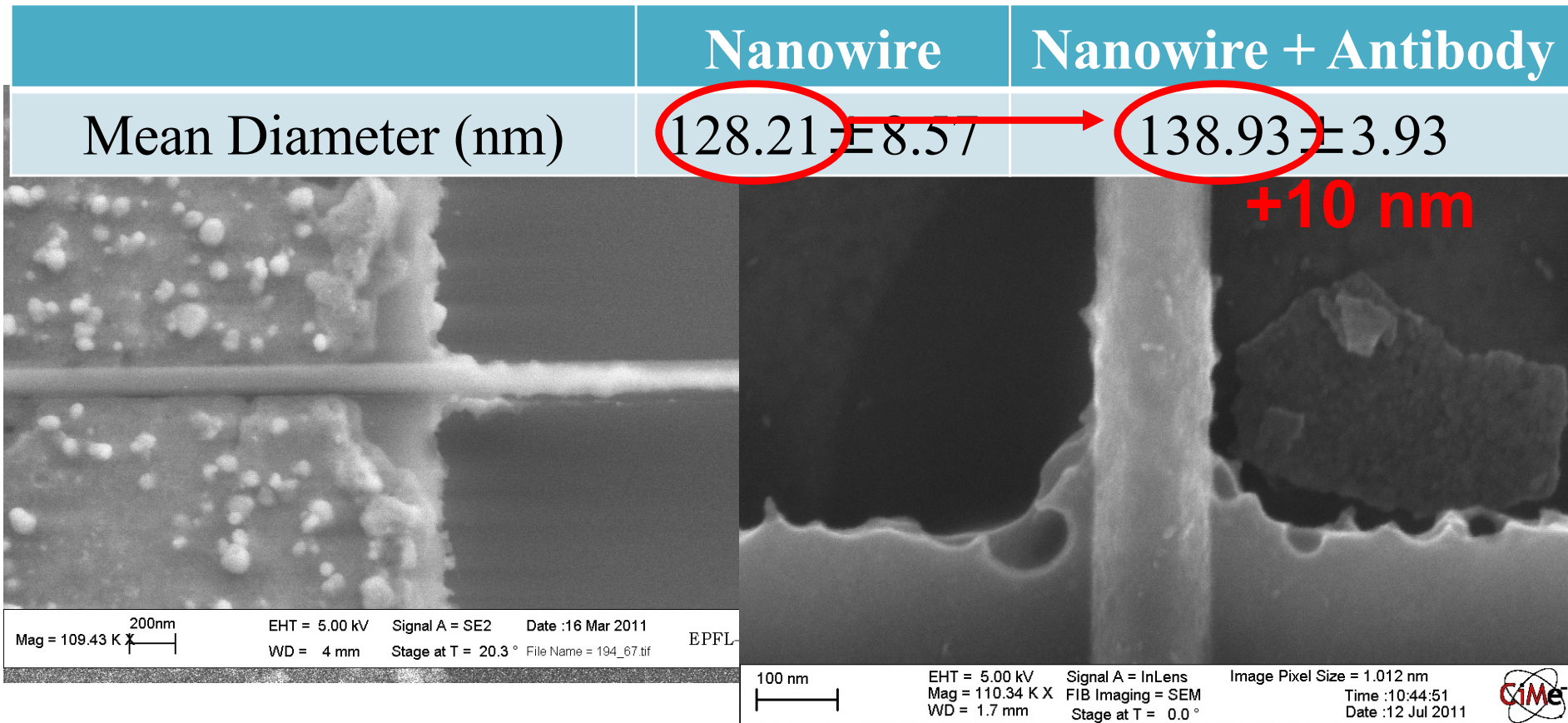
Antibodies against VEGF are deposited by covalent binding on the surface of sensing **NANO-wires**

The size of an Antibody



Bio-Functionalization by SEM

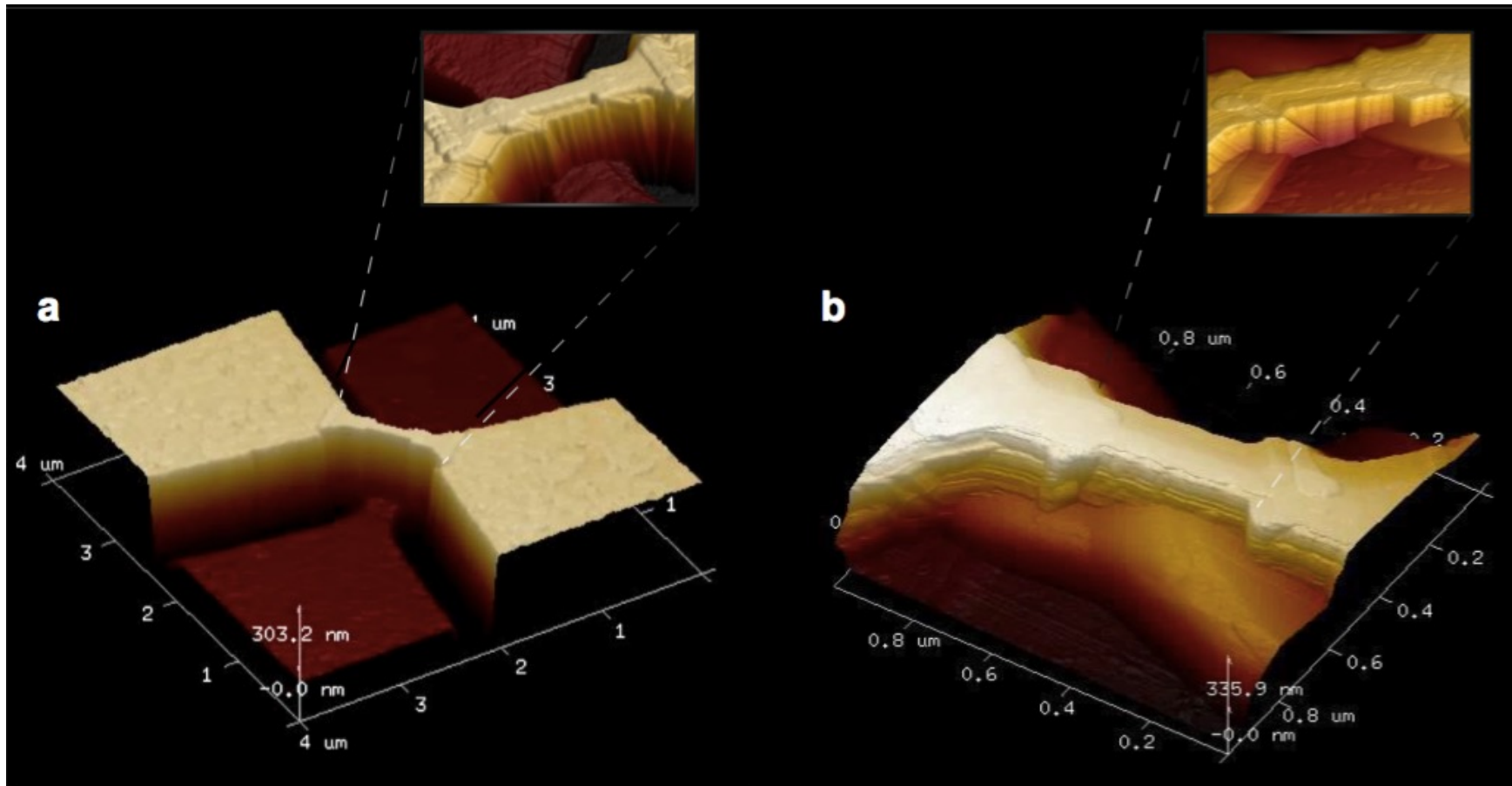
Diameter measurements:



Before (left) and after (right) modification
with anti-VEGF antibodies

Bio-Functionalization by AFM

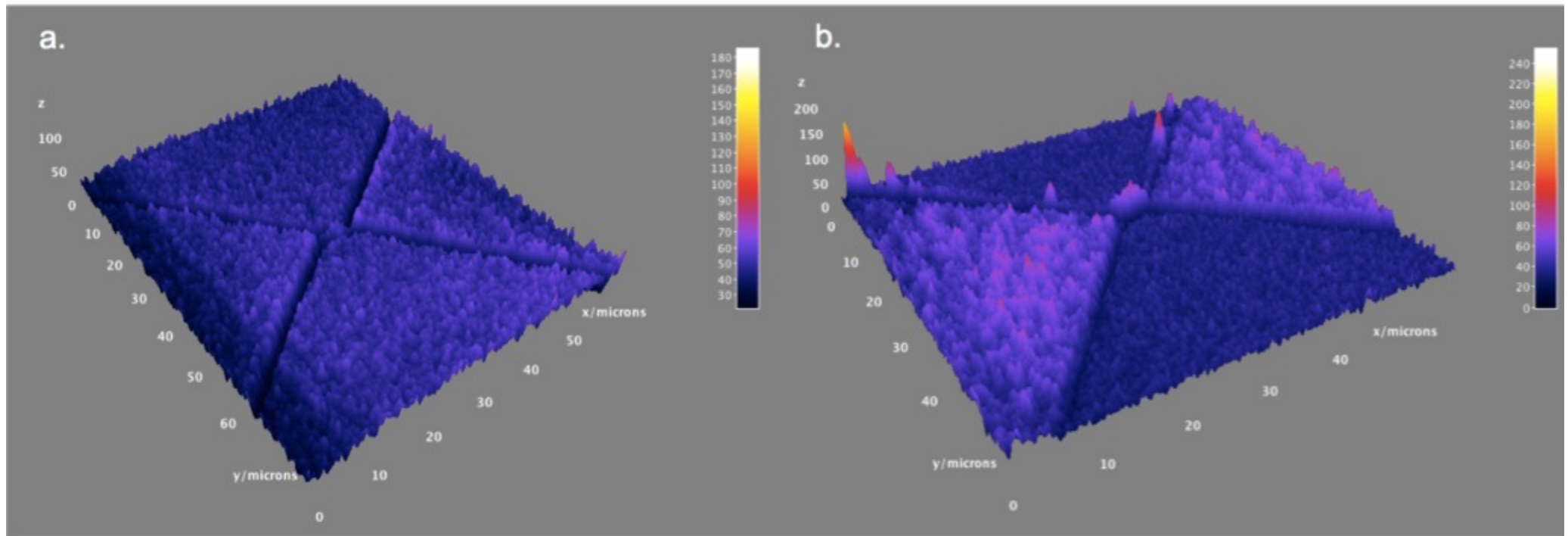
I. Tzouvadaki et al., Journal of Materials Chemistry B., 2016, in press



Before (left) and after (right) the modification with PSA antibodies

Bio-Functionalization by Fluorescence

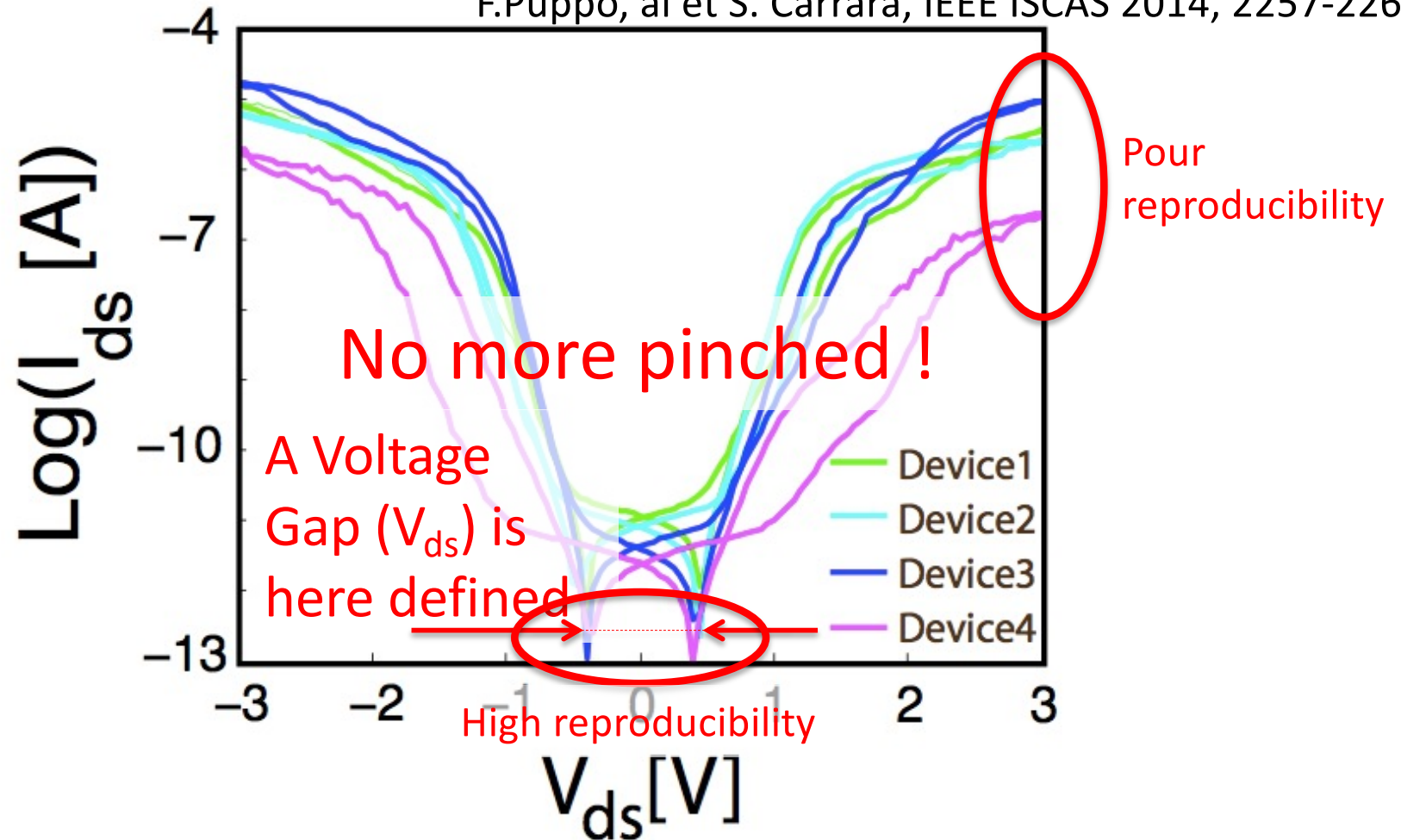
I. Tzouvadaki et al., Journal of Materials Chemistry B., 2016, in press



Before (left) and after (right) the modification with PSA antibodies

Functionalization with Antibodies

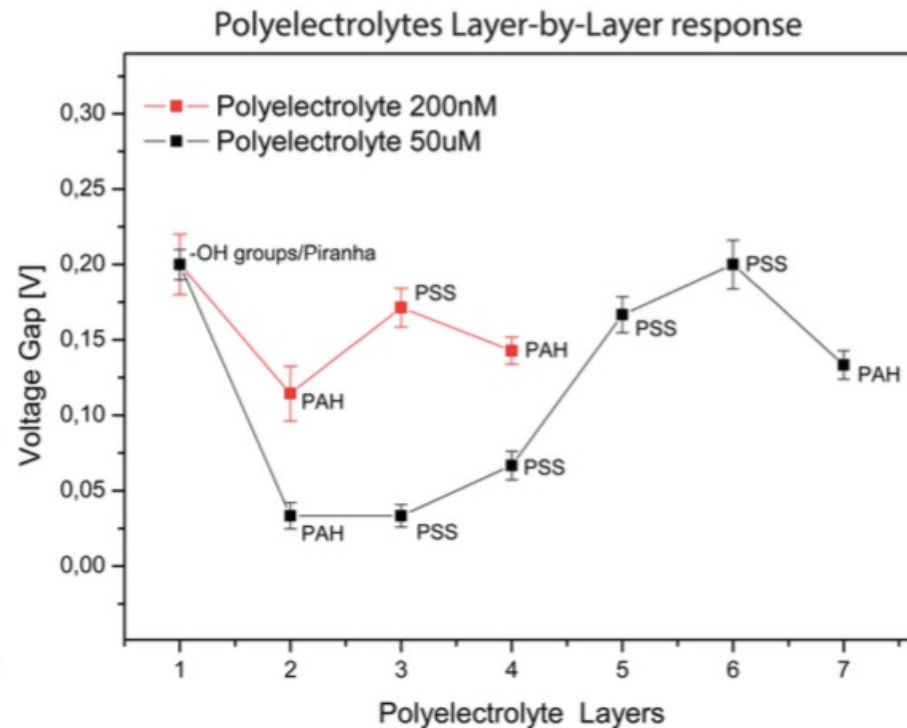
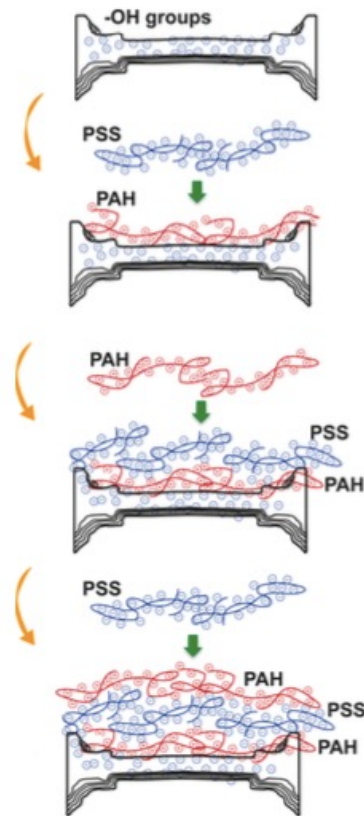
F.Puppo, al et S. Carrara, IEEE ISCAS 2014, 2257-2260



Fully punched Memristive Hysteresis is lost on bio-functionalized nanowires

Layer-by-Layer Charges Transfer

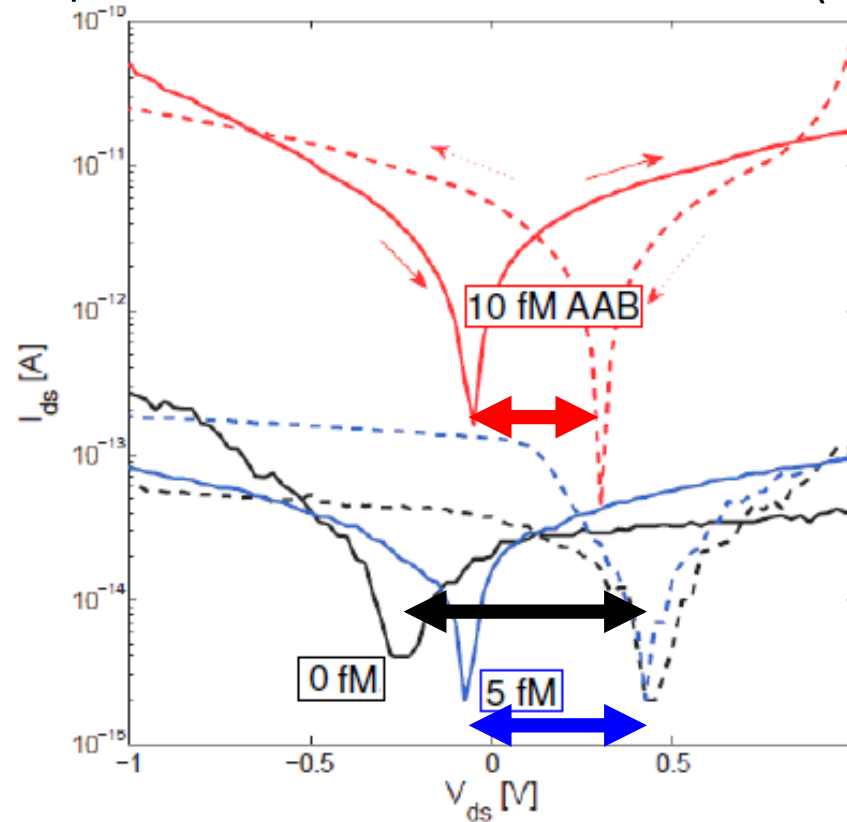
I. Tzouvadaki et al., Nano Letters, 16(2016) 4472-4476



Negatively (PSS) or Positively (PAH) charged polymers change the V_{gap} in opposite directions

Bio-Detection affects Memristive lost

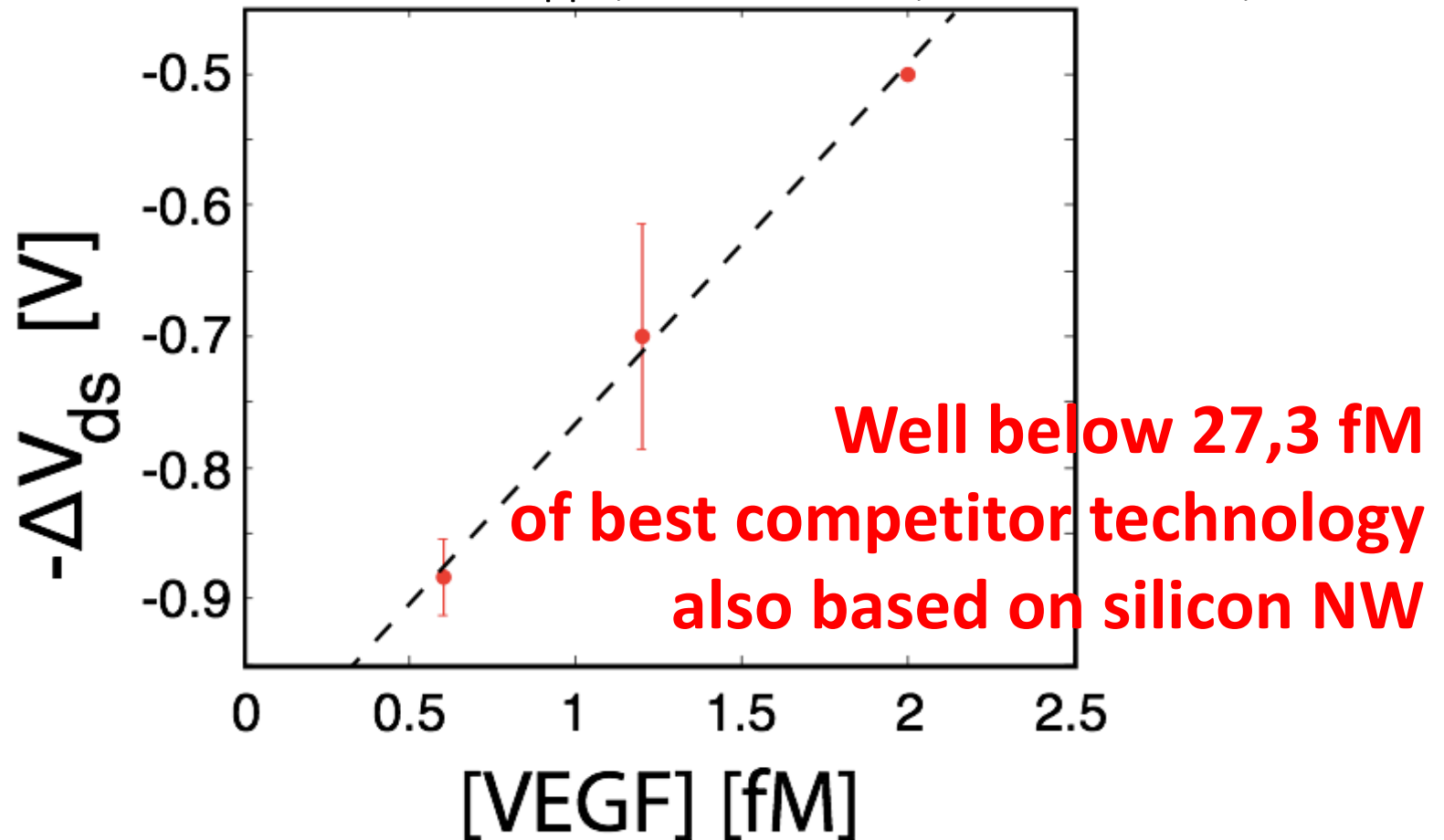
S. Carrara, D. Sacchetto et al. / *Sensors and Actuators B* 171–172 (2012) 449–457



Current minima gaps clearly showing the trend of memristive-biosensors behavior with increasing antigen concentration

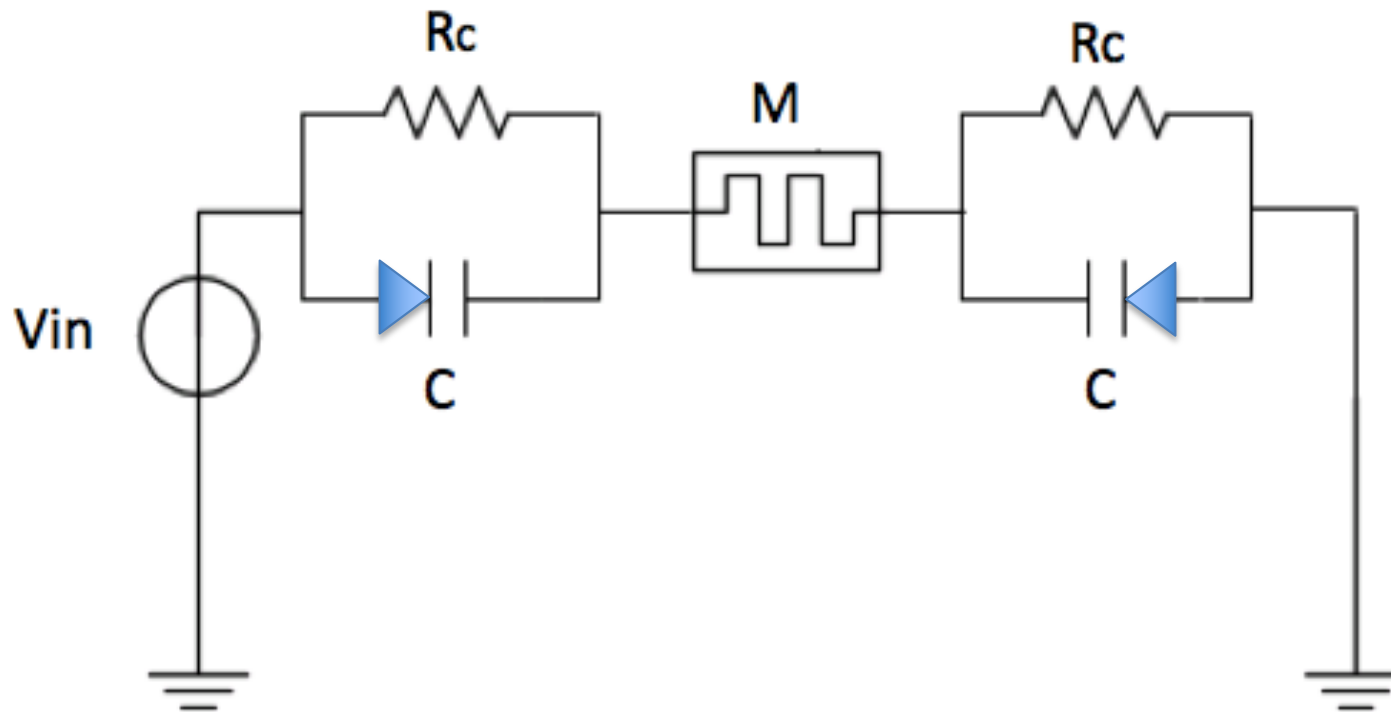
Tumour Marker Detection

F.Puppo, al et S. Carrara, IEEE ISCAS 2014, 2257-2260



The Voltage Gap (V_{ds}) is used to detect the Vascular Endothelial Growth Factor (VEGF)

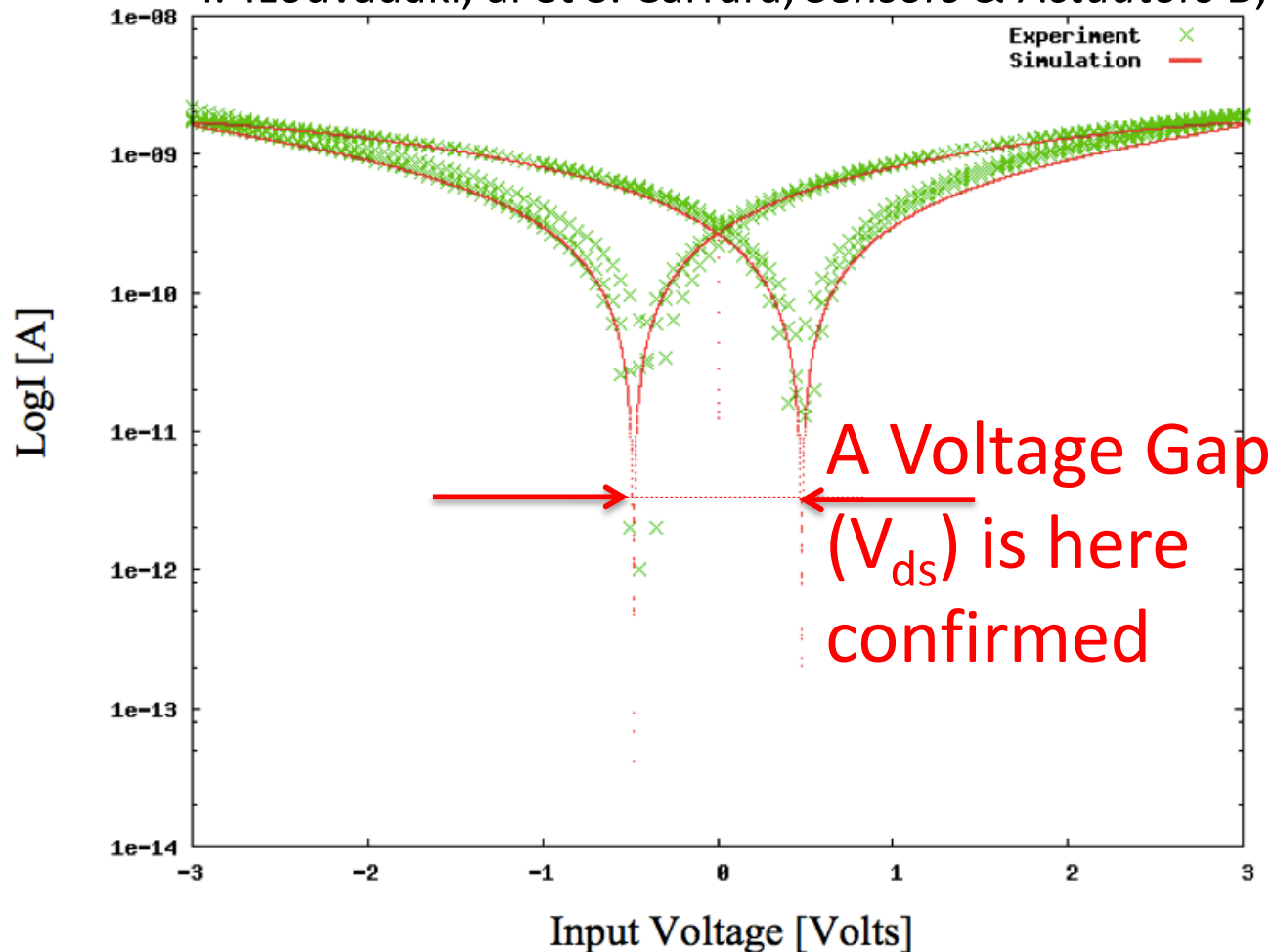
Memristive Model



The Non-pinched Hysteresis is initially modelled by the capacitance of the two Schottky Barriers

Memristive Model Results

I. Tzouvadaki, et al et S. Carrara, *Sensors & Actuators B*, 2014, submitted



The Model fit very well the non-pinched Hysteresis acquired on bio-functionalized nanowires

Memristive Model

I. Tzouvadaki, et al et S. Carrara, *IEEE Sensors Journal* 15(2014) 6208-6217

Antigen concentration [fM]	Voltage gap [Volts] <i>Experimental values</i> [9]	Capacitance (C) [nF]	Voltage gap [Volts] <i>Simulation values</i>
0	0.84	36	0.844
5	0.56	24	0.563
10	0.37	15	0.362

Typical values of the excess capacitance reported in literature are **around 43nF**. It is the combination of the space charge capacitance characterizing the diode and of the diffusion capacitances due to the carriers injection

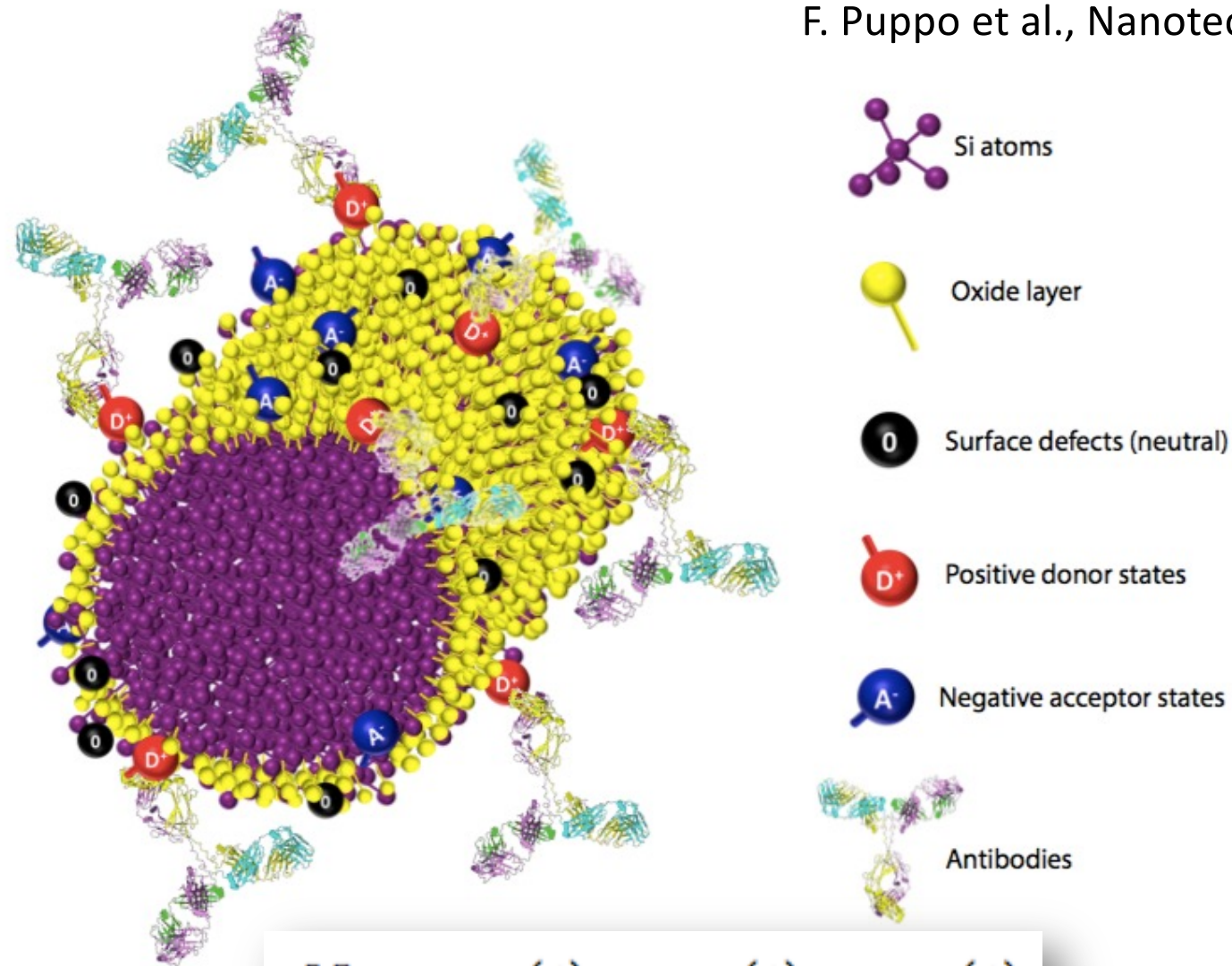
J. Werner, et al., *Phys. Rev. Lett.*, 1988, **60**, 53-56

While typical capacitance values concerning only contributions by the depletion area are in the range of pF

M. Bleicher & E. Lange, *Solid State Electron.*, 1973, 16, 375-380

Surface Trap Mediated Electronic Transport

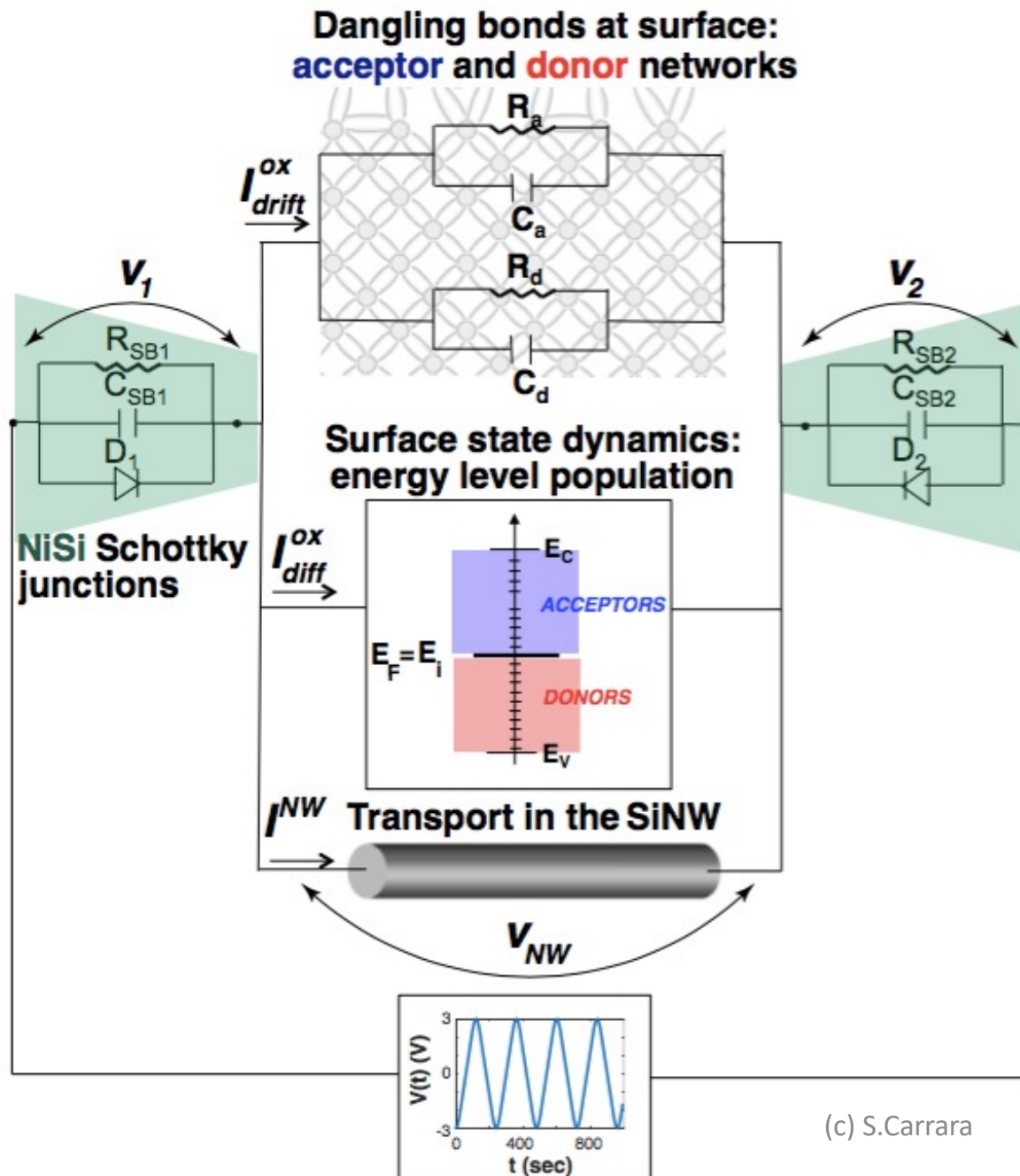
F. Puppo et al., Nanotechnology, 2016



$$N_0 = n_a(t) + n_d(t) + n_n(t)$$

Surface Trap Mediated Electronic Transport

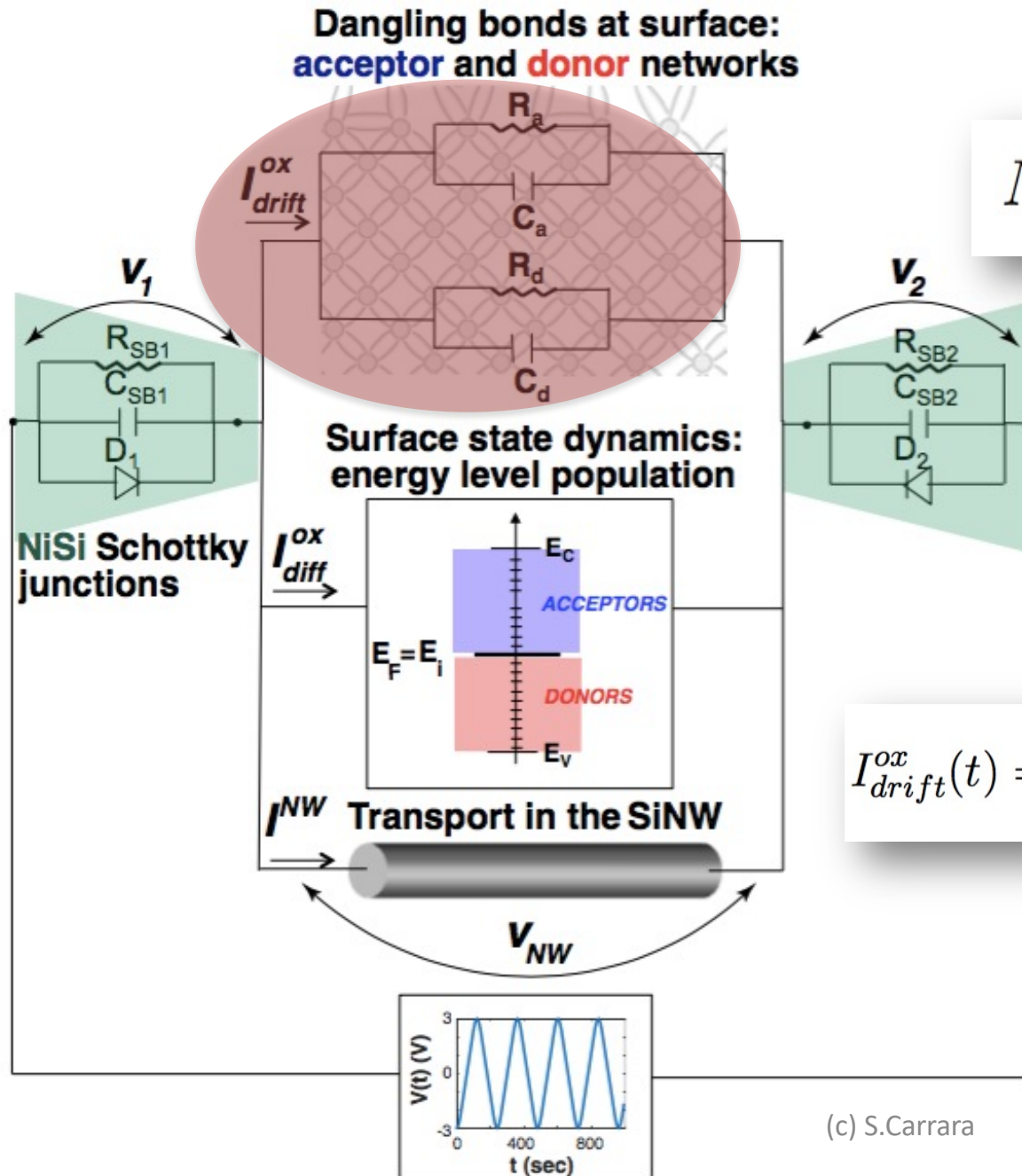
F. Puppo et al., Nanotechnology, 2016,



Equivalent circuit
Modeling the
different mechanisms
of transport in the
memristive nanowire

Surface Trap Mediated Electronic Transport

F. Puppo et al., Nanotechnology, 2016



$$N_0 = n_a(t) + n_d(t) + n_n(t)$$

$$R_\alpha = \left[\frac{qn_\alpha \mu_\alpha}{L} A e^{\frac{\Delta E}{k_B T}} \right]^{-1}$$

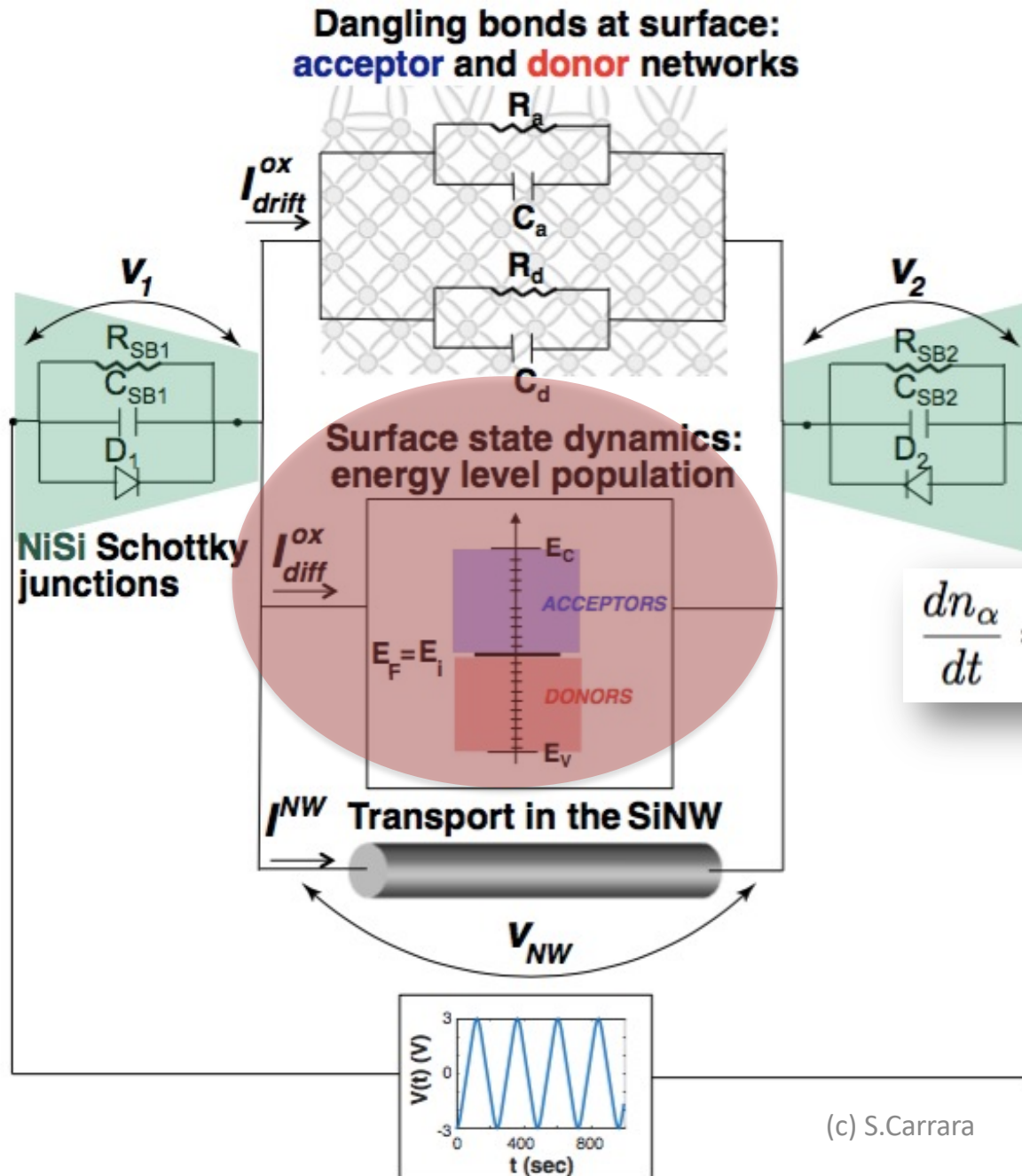
$$C_\alpha = \tilde{C}_\alpha \frac{n_\alpha(t)}{N_0}$$

$$I_{drift}^{ox}(t) = \frac{R_a + R_d}{R_a R_d} V_{NW}(t) + \frac{d}{dt} [(C_a + C_d) V_{NW}]$$

(c) S.Carrara

Surface Trap Mediated Electronic Transport

F. Puppo et al., Nanotechnology, 2016



$$N_0 = n_a(t) + n_d(t) + n_n(t)$$

$$I_{diff}^{ox} = e \left(-f_a \frac{dn_a(t)}{dt} + f_d \frac{dn_d(t)}{dt} \right)$$

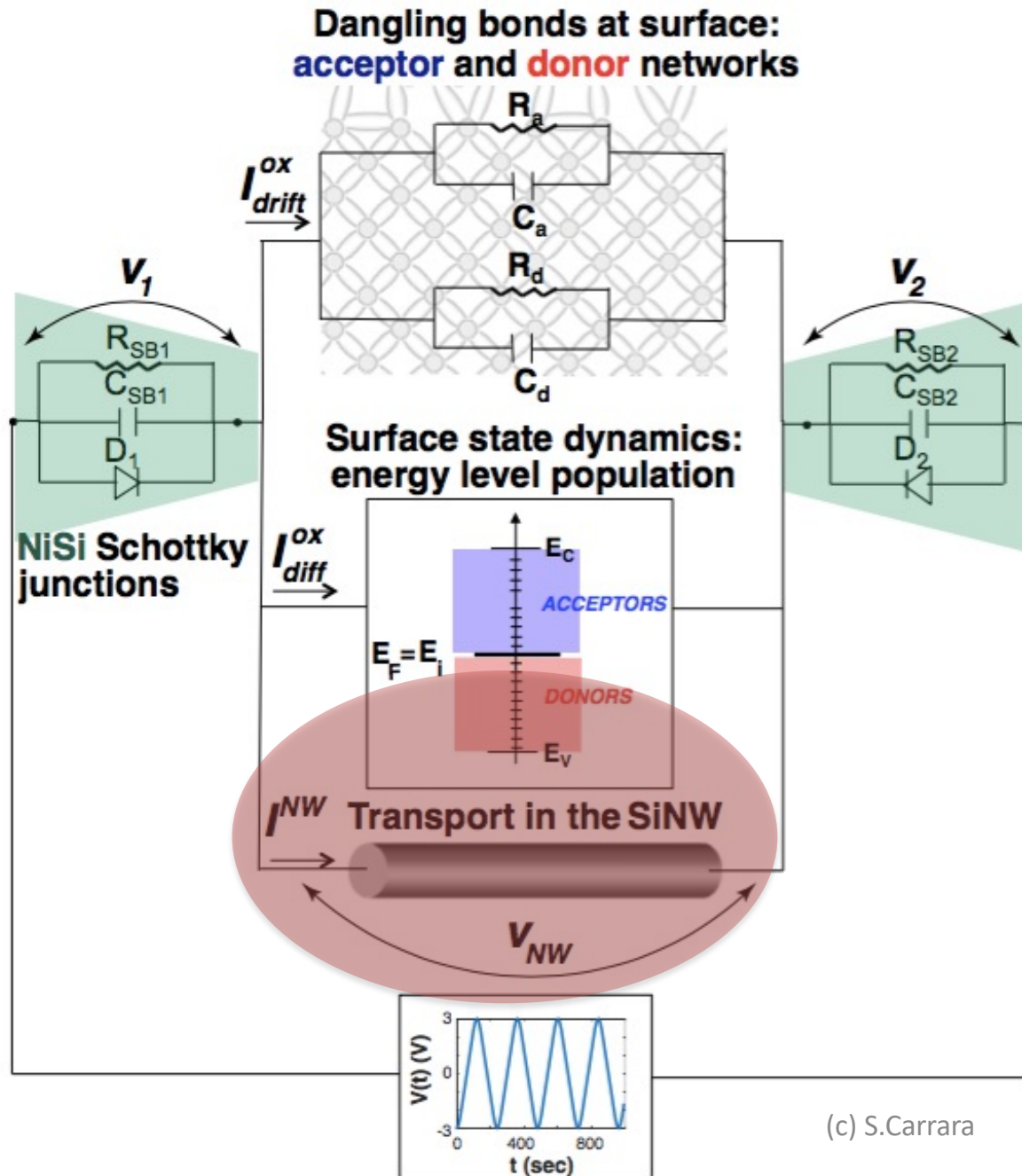
$$\frac{dn_\alpha}{dt} = -k_\alpha^\alpha(V_{NW})n_a + k_n^\alpha(V_{NW})n_n$$

$$k_\alpha^\alpha(V_{NW}) = k_{\alpha 0}^\alpha e^{\frac{-\beta_\alpha(E_\alpha^\alpha - eV_{NW})}{\sigma T}}$$

$$k_n^\alpha(V_{NW}) = k_{n 0}^\alpha e^{\frac{(1-\beta_\alpha)(E_n^\alpha - eV_{NW})}{\sigma T}}$$

Surface Trap Mediated Electronic Transport

F. Puppo et al., Nanotechnology, 2016



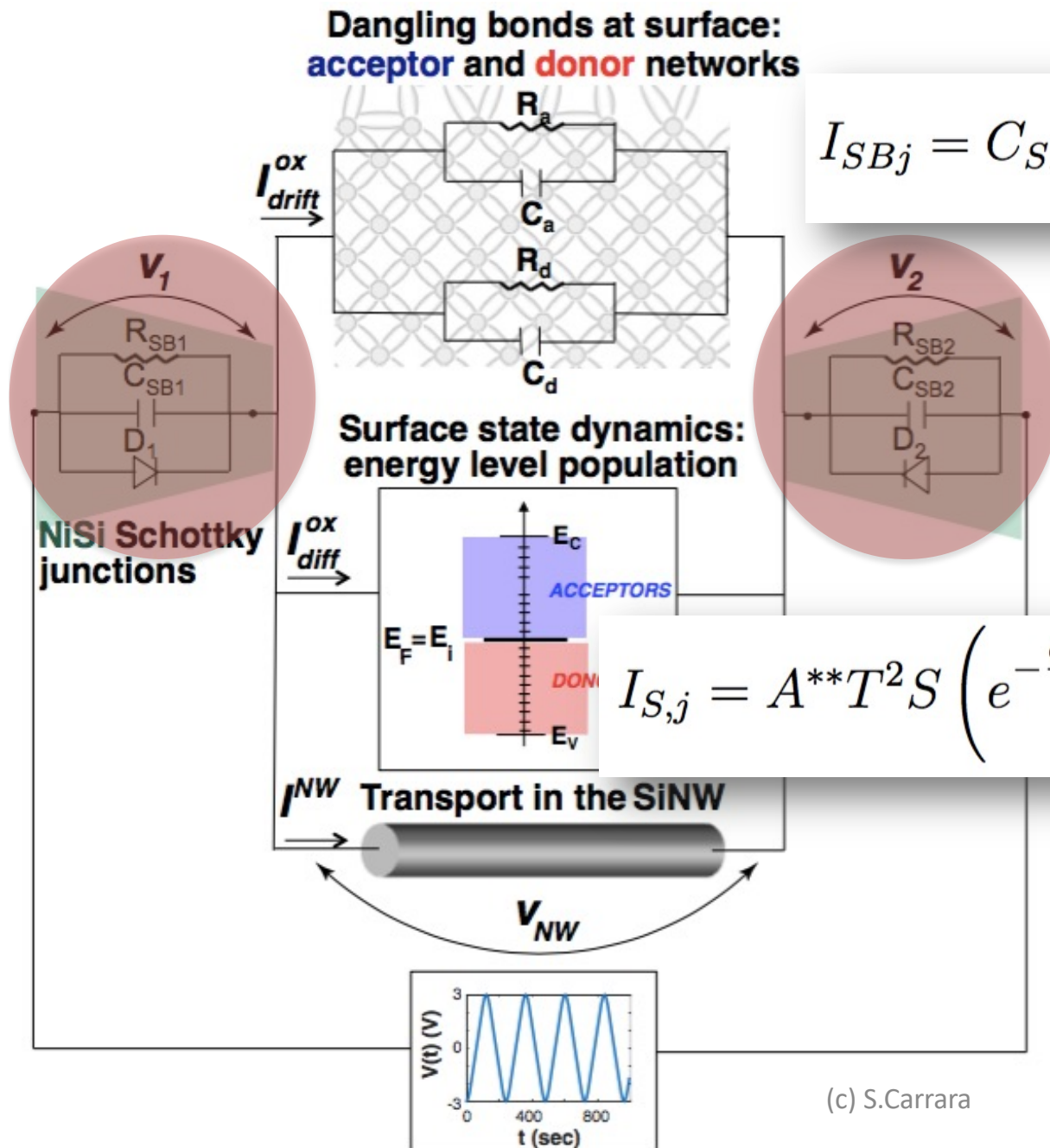
$$I_{drift}^{NW} = \frac{V_{NW}}{R_{Si}}$$

$$I_{diff}^{NW} = -f_s \frac{d(Q_1 + Q_2)}{dt}$$

(c) S.Carrara

Surface Trap Mediated Electronic Transport

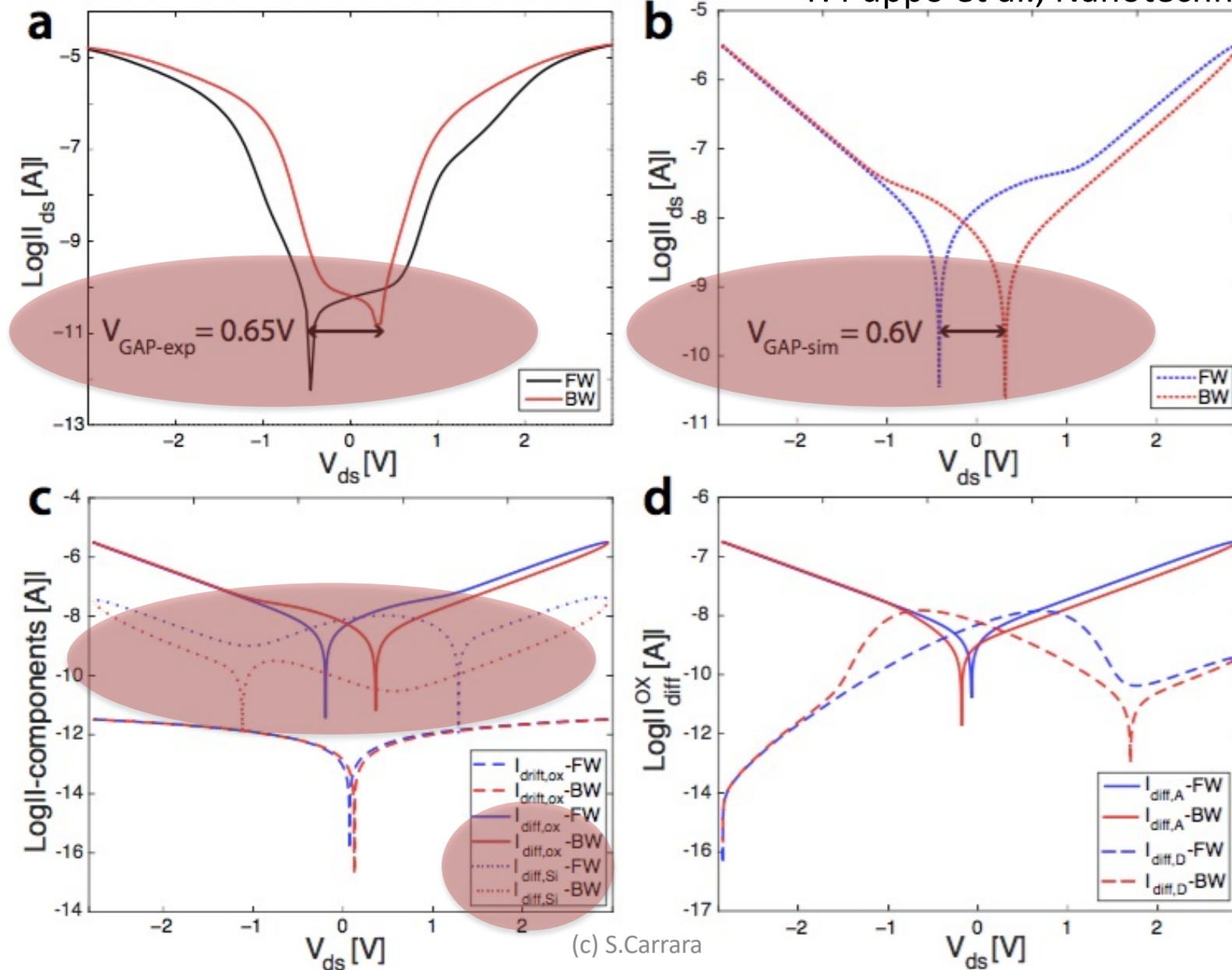
F. Puppo et al., Nanotechnology, 2016



(c) S.Carrara

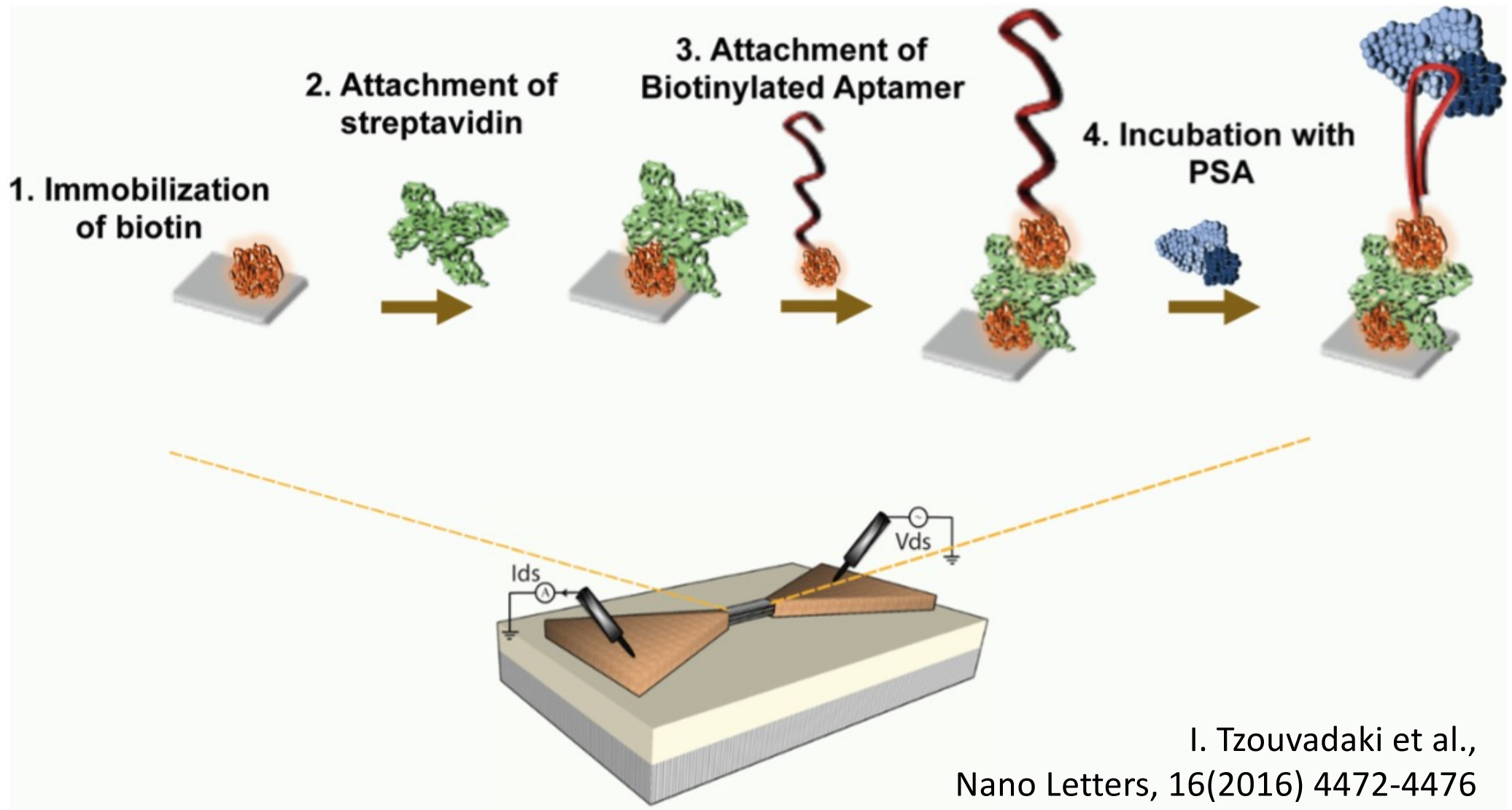
Surface Trap Mediated Electronic Transport

F. Puppo et al., Nanotechnology, 2016



(c) S.Carrara

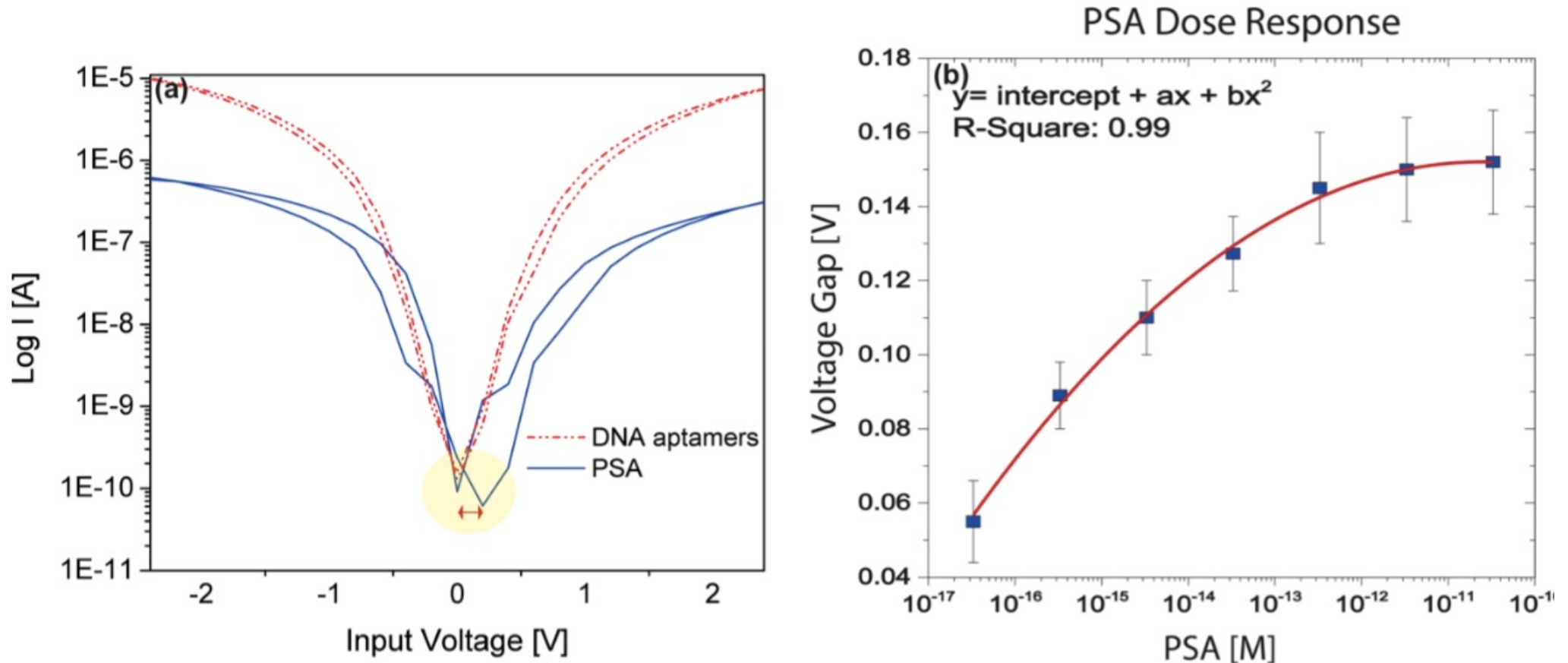
Aptamers Based Memristive Biosensors



I. Tzouvadaki et al.,
Nano Letters, 16(2016) 4472-4476

Memristive Aptamer Sensor for PSA

I. Tzouvadaki et al., Nano Letters, 16(2016) 4472-4476



(a) V_{gap} upon bio-modification and (b) calibration versus dose(response of 10 sensors)

The Best Aptamer Sensors for PSA

I. Tzouvadaki et al., Nano Letters, 16(2016) 4472-4476

Table 1. State of the Art List of Reported PSA Electrochemical Aptasensors to Date

method	electrode surface	LOD	reference
quartz crystal microbalance with dissipation mode/electrochemical impedance spectroscopy (EIS)	gold electrodes	37 nM	Formisano et al. ¹⁴ (2015)
square wave voltammetry	GCE	pM range	Souada et al. ¹⁵ (2015)
EIS	gold electrodes	30 pM	Jolly et al. ¹⁶ (2015)
differential pulse voltammetry (DPV)	glassy carbon electrode (GCE)	7.6 pM	Liu et al. ¹⁷ (2012)
EIS	GCE	0.15 pM	Kavosi et al. ¹⁸ (2015)
EIS	gold electrodes	fM range	Yang et al. ¹⁹ (2015)
EIS (capacitance measurement)	gold electrodes	30 fM	Jolly et al. ²⁰ (2016)
DPV	GCE	300 aM	Kavosi et al. ¹⁸ (2015)
memristive aptasensor	Si-nanowires	23 aM	present work

Our Limit Of Detection (LOD) is now down to 23 aM

Drug Detection: Therapeutics

I. Tzouvadaki et al., Nanoscale, accepted 2017

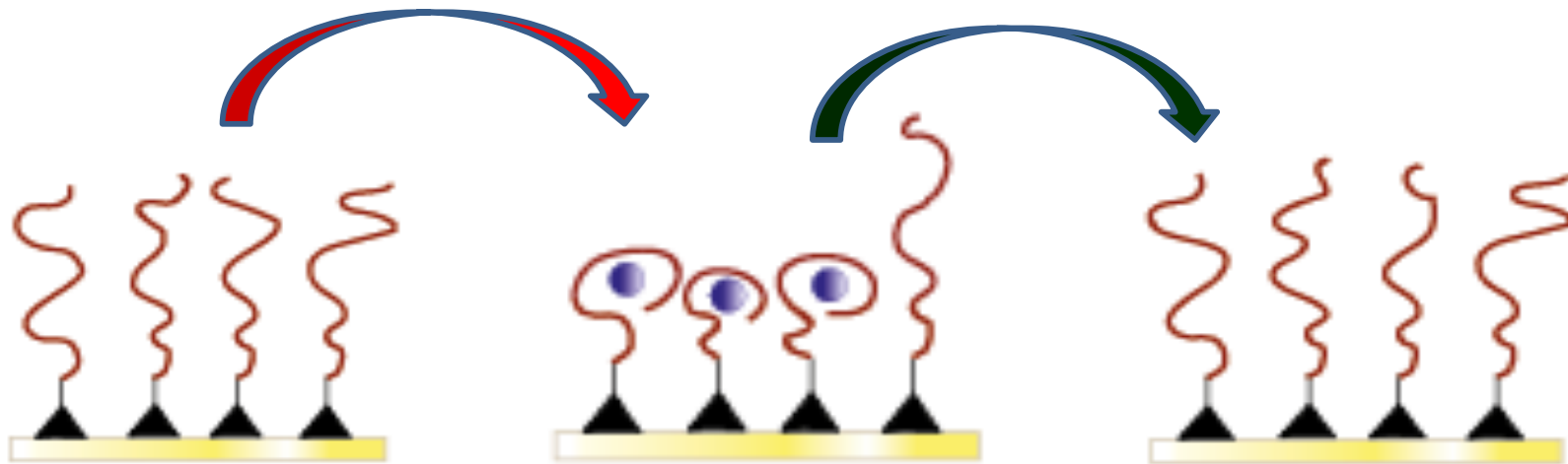
Target drug	Method*	Surface	LOD (nM)		Linear Range (nM)	Ref.	Comments
			Buffer	Bio-matrix			
6-mercaptopurine	Voltam	Graph-ite/Polypyrrole/MWCNT	-	80	200 - 100000	Karimi-Maleh H. (2015)	Diluted human urine
Paracetamol	Voltam	MWCNT*	2.9	-	5 - 1000	Goyal RN. (2010)	-
Penicillin	Voltam	Boron-doped diamond	-	320	400 - 100000	Švorc L. (2012)	Human urine
Tamoxifen	Voltam	Enzyme/Polyaniline/Pt	0.2	-	27 - 297	Radhapyari K. (2013)	-
Clenbuteral	Voltam	Benzedithiol-GNPs*	-	43.96	100 - 800	Bo B. (2013)	Diluted rat urine
Chloramphenicol	Ampero	Cds NPs/GNPs	0.14	-	0.15 - 2.94	Kim D-M. (2010)	-
Artesunate	Ampero	Gr-Polyaniline Nano-composite	0.031	0.035	0.13 - 1	Radhapyari K. (2013)	Highly diluted human serum
TFV	BSI	Glass chip	2.5	-	Up to 20	Kammer MN (2014)	-
TFV	LC-MS	-	-	680	1360 to 350000	Simiele M. (2015)	Human urine
TFV	Voltam	HMDE*	450	870	Up to 17000	Jain R. (2013)	Diluted and precipitated human plasma
TFV	LC-UV	-	-	10.4	35 to 3480	Barkil ME. (2007)	-
TFV	LC-MS	-	-	7	35 to 3480	Barkil ME. (2007)	-
TFV	Field Effect	MOSFET	1.2 nM	-	1 to 100		-
TFV	Memristive	Si-nanowire arrays	0.0033	3.4	0.001 to 1000	Present work	Undiluted Human serum

Voltam: voltammetry; Conduc: conductance; Ampero: amperometry; BSI: back scattering interferometry; LC: liquid chromatography; MS: mass spectroscopy; UV: ultra violet; MWCNT: multiwalled carbon nanotubes; GNP: gold nanoparticle; HMDE: hanging mercury drop electrode

Aptamer regeneration

□ Drug Continuous monitoring

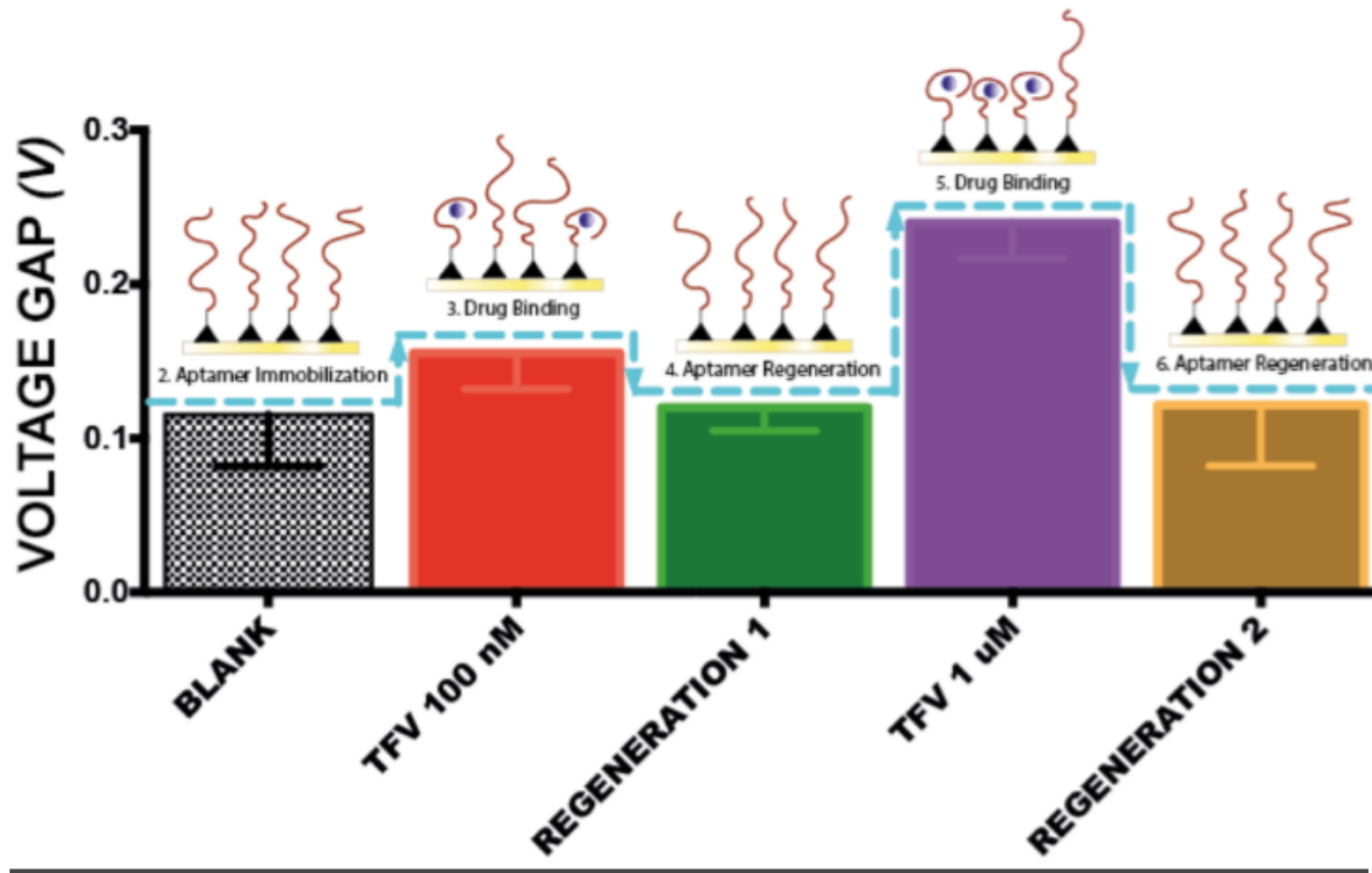
□ Drug Binding – Aptamer unfolding & Drug release



(c) S.Carrara

Aptamer regeneration

I. Tzouvadaki et al., Nanoscale 2017



(c) S.Carrara